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Author and Subject Index

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Author Index (Vol. 110, 1963)

Adams, G. B., *et al.* Photogalvanic Effects with Anodized Zirconium and Niobium Electrodes, 1163

Addamiano, Arrigo, *et al.* Photoluminescence of α-SiC, 517

Agarwal, H. P. Influence of Indifferent Electrolytes on Transfer Coefficient of $Fe(CN)_6^{---}/Fe(CN)_6^{----}$ System, 237

Agruss, B. Thermally Regenerative Liquid-Metal Cell, 1097

Ala, M. A., *et al.* X-Ray Study of Pyrochlore Fluoantimonates of Calcium, Cadmium, and Manganese, 1048

Albers, F. C., *et al.* Radiochemical Studies of Thiourea in the Electroless Deposition Process 890

Aldrich, R. W., *et al.* Gettering of Metallic Impurities from Planar Silicon Diodes, 533

Alt, L. L. *et al.* Gettering of Metallic Impurities from Planar Silicon Diodes, 533
Low-Temperature Deposition of Silicon Oxide Films, 465

Anderson, J. L., *et al.* Low-Temperature Thermal Expansion of the Group 4a Carbides, 587

Andrew, K. F., *et al.* Oxidation of Graphite at Temperatures of 600° to 1500°C and at Pressures of 2 to 76 Torr of Oxygen, 476
Oxidation of Molybdenum 550° to 1700°C, 952
Vapor Pressure of Molybdenum Trioxide, 242

Anson, F. C. Electro-Oxidation of Ethylenediaminetetraacetocobalt (II) at Platinum Electrodes. Effects of Anion Adsorption, 436

Anson, F. C., *et al.* Integration of Single-Sweep Oscillopolarograms, I. Determination of Reactant Adsorption and Oxide Film Reduction at Platinum Electrodes, 926

Antill, J. E., and Peakall, K. A. Mechanism of the Oxidation of a Uranium-One Weight Per Cent Copper Alloy, 1146

Apple, E. F. Observations on the Formation of Color Centers in Calcium Halophosphates, 374; (c), 1230

Aronowitz, Gerald, and Hackerman, Norman. Passivity of Iron-Chromium Alloys, 633

Aven, M., and Garwacki, W. Epitaxial Growth and Properties of ZnTe-CdS Heterojunctions, 401

Ayers, R. C., Jr., and Hackerman, Norman. Corrosion Inhibition in HCl Using Methyl Pyridines, 507

Baba, Hideo. Some Effects of Zinc Atmospheres on Zinc Sulfide, 79

Baird, D. H., *et al.* Influence of Copper on Structural Transformations in ZnS.Cu,Cl, 1228

Balk, P., and Peterson, E. L. Properties of $HF-H_2O_2$ Treated Germanium Surfaces, 1245

Bannon, W. J., *et al.* Effect of Pressure or the Conductivity of Battery Electrolytes, 1282

Banter, J. C., *et al.* Electrochemistry of Nickel, II. Anodic Polarization of Nickel, 1007

Barnes, C. R., and Geesner, C. R. Pyrolytic Deposition of Silicon Dioxide for 600°C Thin Film Capacitors, 361

Bartlett, R. W., *et al.* High-Pressure Oxidation of Metals, Nickel in Oxygen, 185

Baur, J. P., *et al.* High-Pressure Oxidation of Metals, Nickel in Oxygen, 185

Beck, W., *et al.* Technique for the Evaluation of Hydrogen Embrittlement Characteristics of Electroplating Baths, 886

Beckmann, G. E. J. Growth of Silicon Carbide from Molten Silicon, 84

Behringer, A. J., and Corrsin, Lester. X-Ray Diffraction Study of Evaporated CdS Films, 1083

Berg, Daniel, and Tanaka, John. Effect of the Dielectric Constant of the Embedding Media on Electroluminescent Light Intensity, 580

Berger, Carl, *et al.* Ion Exchange Membrane Properties—Their Effect on the Development of the Dual Membrane Fuel Cells, 1173

Bergh, A. A. Spreading of Molten Indium Over Germanium, 908

Bergh, A. A., and Holschwandner, L. H. Uniformity of the Wetting and Dissolution of Germanium by Molten Indium, 904

Berlin, Alice, *et al.* Ion Exchange on Single-Crystal Silver and Zinc, 1261

Bertocci, Ugo, *et al.* On the Formation of Electrochemical Etch Pits on the (111) Face of Copper, 1190

Bhatia, B. K., and Straumanis, M. E. Disintegration of Magnesium While Dissolving Anodically in Neutral and Acidic Solutions, 357

Bhatia, B. K., *et al.* Difference Effect on Magnesium Dissolving in Acids, 1117

Bicelli, L. P. (d), 1291

Blakeslee, A. E., and Yeh, T. H. Junction Delineation in Gallium Arsenide, 1018

Block, M., and Spiegler, K. S. Transport of Bicarbonate, Carbonate, and Chloride Ions through Ion Exchange Membranes, 577

Blumenthal, R. N., and Whitmore, D. H. Thermodynamic Study of Phase Equilibria in the Titanium-Oxygen System within the $TiO_{1.95}$-TiO_2 Region, 92

Bockris, J. O'M., and Damjanovic, A. Kinetics of the Electrodeposition and Dissolution of Metal Monolayers as a Function of Dislocation Density, 1035

Bockstie, L., *et al.* Control of Al Corrosion in Caustic Solutions, 267

Boddy, P. J., and Brattain, W. H. Distribution of Potential at the Germanium Aqueous Electrolyte Interface, 570

Boddy, P. J., and Sundburg, W. J. Capacity Measurements on Rapidly Polarized Germanium Electrodes, 1170

Boggs, W. E., *et al.* Effect of Alloying Elements on the Oxidation of Tin, 4

Bond, P., *et al.* Corrosion and Passivity of Molybdenum-Nickel Alloys in Hydrochloric Acid, 650

Bowman, M. G., *et al.* Mutual Solid Solubility of Hafnium Carbide and Uranium Monocarbide, 560

Bradhurst, D. H. (d), 1289

Bradley, Arthur, and Hammes, J. P. Electrical Properties of Thin Organic Films, 15
Photoconductivity in Thin Organic Films, 543

Bradley, R. R., and Joyce, B. A. Epitaxial Growth of Silicon from the Pyrolysis of Monosilane on Silicon Substrates, 1235

Brassart, F. A., *et al.* Oxidation of Graphite at Temperatures of 600° to 1500°C and at Pressures of 2 to 76 Torr of Oxygen, 476
Oxidation of Molybdenum 550° to 1700°C, 952
Vapor Pressure of Molybdenum Trioxide, 242

Brattain, W. H., and Boddy, P. J. Distribution of Potential at the Germanium Aqueous Electrolyte Interface, 570

Breese, R. F., *et al.* Effect of Electrolyte and Solvent on Polarographic Reductions of Nitrobenzene Derivatives, 995

Breiter, M. W. Anodic Oxidation of Methanol on Platinum, III. Adsorption Kinetics in Acidic Solution, 449

Breiter, M. W., and Weininger, J. L. Effect of Crystal Structure on the Anodic Oxidation of Nickel, 484

Brenner, Abner, and Sligh, J. L. Galvanostalametry: A New Technique, Based on the Negative Pressure of Liquids, for Investigating Electrochemical Phenomena at an Electrode, 1136

Bricker, C. E., *et al.* Formation and Dissolution of Platinum Oxide Film: Mechanism and Kinetics, 826

Britton, C. F., *et al.* Influence of Environment on the Corrosion of Zirconium and Its Alloys in High-Temperature Steam, 856

Brixner, L. H. X-ray Study and Thermoelectric Properties of the $W_xTa_{1-x}Se_2$ System, 289

Brodd, R. J., and DeWane, H. J. Impedance of Leclanche Cells and Batteries, 1091

Broder, J. D., and Wolff, G. A. New Method of GaP Growth, 1150

Brophy, J. H., and Hayden, H. W. Activated Sintering of Tungsten with Group VIII Elements, 805

Brown, G. H., and Hsiung, Hsiao-shu. Polarography of π-Complexes of Cobalt, Chromium, and Titanium in Formamide and Dimethylformamide, 1085

Brown, J. J., and Hummel, F. A. Phase Equilibria and Manganese-Activated Luminescence in the System $Zn_3(PO_4)_2$-$Cd_3(PO_4)_2$, 1218

Brown, W. E., Jr., and Mayer, S. W. Electrode Kinetics for Chlorides of Tungsten, Antimony, and Phosphorus, 306

Bube, R. H., and Dreeben, A. B. Photoconductivity Performance in Large Single Crystals of Cadmium Sulfide, 456

Bucciili, P. R., and Speros, D. M. On the Emission of Electrons from Solids in Gas Discharges, II. Accelerating Field Emission, 748

Cairns, E. J., *et al.* Thermodynamics of Hydrocarbon Fuel Cells, 1025

Campbell, J. J., *et al.* Stress Generation in Tantalum During Oxidation, 551

Cartledge, G. H., and Spahrbier, D. H. Ion-Exchange Properties of the Film on Passive Iron and Steel, 644

Cathcart, J. V., *et al.* Stress Generation in Tantalum During Oxidation, 551

Celmer, P. R., and Weisberg, L. R. Arsenic Purification by Crystal Growth from the Melt, 56

Chen, L. C., and Salomon, R. E. Anodic Oxidation of Boron, 173

Christensen, H., and Kuper, A. B. Crystallographic and Electrical Properties of Epitaxial Germanium, 988

Chu, T. L., and Gavaler, J. R. Stacking Faults in Vapor Grown Silicon, 388

Cisak, Andrzej, and Elving, P. J. Electrochemistry in Pyridine, I. Polarography and Macroscale Electrolysis of Inorganic Salts, 160

Claussen, B. H., and Flower, M. Investigation of the Optical Properties and the Growth of Oxide Films on Silicon, 983

Cline, C. F., and Kahn, J. S. Microhardness of Single Crystals of BeO and Other Wurtzite Compounds, 773

Coates, D. G. Lead Selenide Evaporated Layer Photoconductive Detectors for Room Temperature Operation, 174

Cohen, J. B., *et al.* Effects of Additives on the Structure of Electrodeposited Silver, 103

Cohen, M., *et al.* Introduction to Passivity Symposium Transactions, 596

Cohen, Morris, and Nagayama, Masaichi. Anodic Oxidation of Iron in a Neutral Solution, II. Effect of Ferrous Ion and pH on the Behavior of Passive Iron, 670

Conn, P. K., *et al.* Diffusion Coefficients for Hydrogen in β-Zirconium, 799

Corrsin, Lester, and Behringer, A. J. X-Ray Diffraction Study of Evaporated CdS Films, 1083

Coucoulas, A., *et al.* Reactions Between Refractory Oxides and Graphite, 783

(c) Indicates Correction

(d) Indicates Discussion

(ed) Indicates Editorial

(L. Ed.) Indicates Letter to the Editor

Pages in Each Issue (Vol. 110, 1963)

Month	Technical	Nontechnical
January	1-94	1C-18C
February	95-180	19C-36C
March	181-244	37C-80C
April	245-352	81C-100C
May	353-468	101C-112C
June Sec. I	469-594	113C-130C
Sec. II	595-708	
July	709-852	131C-154C
August	853-946	155C-208C
September	947-1024	209C-226C
October	1025-1090	227C-240C
November	1091-1172	241C-254C
December	1173-1294	255C-276C

Cox, B., and Harder, B. R. Effect of Dissolved Oxygen on the Oxidation of Zircaloy-2 by Steam, 1110
Cronin, G. R., *et al.* Growth of Crystals from Compounds with Volatile Components, 582
Cunningham, J. A., and Watt, G. W. Mechanism of Electrodeposition from Aqueous Solutions of Square Planar Complexes, 716

Dahms, Harald, and Green, Mino. Adsorption of Aromatic Hydrocarbons at the Gold Electrolyte Interface, 1075
New Method for the Determination of the Zero Charge Point of Metal Electrodes, 466
Damjanovic, A., and Bockris, J. O'M. Kinetics of the Electrodeposition and Dissolution of Metal Monolayers as a Function of Dislocation Density, 1035
Damm, E. P., Jr. (d), 590
Davies, J. A., and Domeij, B. Use of α-Spectroscopy for Studying Anodic Oxidation, 849
Deal, B. E. Oxidation of Silicon in Dry Oxygen, Wet Oxygen, and Steam, 527; (d), 1292; Supplementary data, 1292
Delgrosso, E. J., and Harrison, R. W. Formation of a Zinc Oxide-Niobium Pentoxide Spinel, 205
Demendi, J. F., *et al.* Porous Carbon Gas Diffusion Electrodes, 932
Devanathan, M. A. V., *et al.* Technique for the Evaluation of Hydrogen Embrittlement Characteristics of Electroplating Baths, 886
DeWane, H. J., and Brodd, R. J. Impedance of Leclanche Cells and Batteries, 1091
Dixon, J. M., *et al.* Electrical Resistivity of Stabilized Zirconia at Elevated Temperatures, 276
Domeij, B., and Davies, J. A. Use of α-Spectroscopy for Studying Anodic Oxidation, 849
Draley, J. E., *et al.* Corrosion of 1100 Aluminum in Oxygen-Saturated Water at 70°C, 622
Dreeben, Arthur. Effect of CdS on the Electroluminescence of ZnS:Cu, Halide Phosphors, 1045
Dreeben, A. B., and Bube, R. H. Photoconductivity Performance in Large Single Crystals of Cadmium Sulfide, 456
Duby, Paul, and Kellogg, H. H. Measurement of "Pressure-EMF" in Pure Fused Salts, 349
Duke, F. R., and Victor, George. Transport Numbers of Some Pure Fused Nitrates and Nitrites, 91
Duke, F. R., and Wolf, E. D. Transference Numbers and Ion Association in Pure Fused Alkaline Earth Chlorides, 311

Eiss, Roger, and Frant, M. S. Conductivity and Thermoelectric Potential Measurements on Perylene: Metal Halide Complexes, 769
Elder, J. P. (d), 591
Elie, G., *et al.* Some Factors Affecting the Degradation of GaAs Tunnel Diodes, 178
Elliott, J. F., and Weinstein, Martin. Thermodynamic Properties of the Manganese-Lead-Bismuth System, 792
Elving, P. J., and Cisak, Andrzej. Electrochemistry in Pyridine, I. Polarography and Macroscale Electrolysis of Inorganic Salts, 160
Elving, P. J., and Grodzka, P. G. Polarographic Reduction of the Phenyl-Substituted Ethenes, I. Relation of Postulated Mechanisms to Theoretical Behavior Patterns, 225; II. Electrochemical Kinetic Parameters and Mechanism in Dimethylformamide, 231
Enck, E. G., and Faust, C. L. (ed) Page Charge Adopted for the Journal, 257C
Enke, C. G., *et al.* Formation and Dissolution of Platinum Oxide Film: Mechanism and Kinetics, 826
Ervin, Guy, Jr., and Nakata, M. M. Oxidation Kinetics of $ZrBe_{13}$ and $NbBe_{12}$, 1103
Escoffery, C. A. (d), 1291
Evans, U. R. (d), 1290

Fassell, W. M., Jr., *et al.* High-Pressure Oxidation of Metals, Nickel in Oxygen, 185
Fatueva, T. A., and Vagramyan, A. T. On the Theory of Simultaneous Discharge of Metal Ions in Real Conjugated Systems, 1030
Faust, C. L. (ed) Appeal to Authors, 21C
Faust, C. L., and Enck, E. G. (ed) Page Charge Adopted for the Journal, 257C
Faust, J. W., Jr., and John, H. F. Growth Twins in the F.C.C. Metals, 463; (d), 1291
Faust, J. W., Jr., and Nicholson, H. Dendritic Growth of InSb, 940
Feldberg, S. W., *et al.* Formation and Dissolution of Platinum Oxide Film: Mechanism and Kinetics, 826
Feller, H., *et al.* Corrosion and Passivity of Molybdenum-Nickel Alloys in Hydrochloric Acid, 650
Finkelstein, Manuel, *et al.* Electrochemical Degradation of Aryl Sulfonium Salts, 422
Finne, R. M., *et al.* Electropolishing Technique for Germanium and Silicon, 412
Fischer, A. G. Electroluminescent Lines in ZnS Powder Particles, II. Models and Comparison with Experience, 733
Fischer, J., *et al.* Mechanism of the Nickel-Fluorine Reaction, 346
Flannery, R. J., *et al.* Behavior of Germanium Electrodes in a Ziegler Electrolyte, 1054
Fleischmann, M., and Thirsk, H. R. Growth of Thin Passivating Layers on Metallic Surfaces, 688
Fleitman, A. H., *et al.* Corrosion of Carbon Steel by High-Temperature Liquid Mercury, 964
Flower, M., and Claussen, B. H. Investigation of the Optical Properties and the Growth of Oxide Films on Silicon, 983
Franklin, R. W., and Stirland, D. J. Studies on the Structure of Anodic Oxide Films on Aluminum, II, 262
Frant, M. S., and Eiss, Roger. Conductivity and Thermoelectric Potential Measurements on Perylene: Metal Halide Complexes 769
Frysinger, G. R., *et al.* Effect of Pressure on the Conductivity of Battery Electrolytes, 1282
Fujii, C. T., and Meussner, R. A. Oxide Structures Produced on Iron-Chromium Alloys by a Dissociative Mechanism, 1195

Galiotto, R. J., and Katan, T. Current Efficiencies for the Anodic Oxidation of Ammonia in Potassium Hydroxide Solution, 1022
Gallaccio, A., *et al.* Electrophoretic Deposition of Metals, 843
Garwacki, W., and Aven, M. Epitaxial Growth and Properties of ZnTe-CdS Heterojunctions, 401
Gavaler, J. R., and Chu, T. L. Stacking Faults in Vapor Grown Silicon, 388
Geesner, C. R., and Barnes, C. R. Pyrolytic Deposition of Silicon Dioxide for 600°C Thin Film Capacitors, 361
Gelezunas, V. L., *et al.* Diffusion Coefficients for Hydrogen in β-Zirconium, 799
Gerischer, H., and Roe, D. K. Preparation of Spherical Single Crystal Electrodes for Use in Electrocrystallization Studies, 350
Glang, Reinhard, *et al.* Vacuum Evaporation of Cadmium Telluride, 407; (d) 1291
Glatz, A. C., and Meikleham, V. F. Preparation and Electrical Properties of Bismuth Trisulfide, 1231
Glicksman, R. Investigation of the Electrochemical Characteristics of Organic Compounds, X. Sulfur Compounds, 353
Glicksman, R., *et al.* Some Factors Affecting the Degradation of GaAs Tunnel Diodes, 178
Goldberg, P., *et al.* Influence of Copper on Structural Transformations in ZnS:Cu,Cl, 1228
Goldsmith, N. Growth Rates of Epitaxial Gallium Arsenide, 588
Gossenberger, H. F., *et al.* Method for the Preparation of Low-Temperature Alloyed Gold Contacts to Silicon and Germanium, 239
Graven, W. M., *et al.* Photogalvanic Effects with Anodized Zirconium and Niobium Electrodes, 1163
Gray, W. F. M. (ed) Shocking Discovery, 210C
Graydon, W. F., and Kagetsu, T. J. Dissolution of Brass in Sulfuric Acid Solutions, II. 95/5 Brass, 709
Green, Mino, and Dahms, Harald. Adsorption of Aromatic Hydrocarbons at the Gold Electrolyte Interface, 1075
New Method for the Determination of the Zero Charge Point of Metal Electrodes, 466
Greene, N. D., and Steigerwald, R. F. Anodic Dissolution of Binary Alloys (d), 592
Gregory, D. P., and Williams, K. R. Electrolytes for Low-Temperature Fuel Cells, 209
Grieco, M. J., and Miller, K. J. Epitaxial P-Type Germanium and Silicon Films by the Hydrogen Reduction of $GeBr_4$, $SiBr_4$, and BBr_3, 1252
Grodzka, P. G., and Elving, P. J. Polarographic Reduction of the Phenyl-Substituted Ethenes, I. Relation of Postulated Mechanisms to Theoretical Behavior Patterns, 225; II. Electrochemical Kinetic Parameters and Mechanism in Dimethylformamide, 231
Grossman, J. J. Kinetic Theory for Autodoping for Vapor Phase Epitaxial Growth of Germanium, 1065
Grubb, W. T., and Niedrach, L. W. High Performance Saturated Hydrocarbon Fuel Cell, 1086
Gruss, L. L., and McNeill, William. Anodic Film Growth by Anion Deposition in Aluminate, Tungstate, and Phosphate Solutions, 853
Gulbransen, E. A., *et al.* Oxidation of Graphite at Temperatures of 600° to 1500°C and at Pressures of 2 to 76 Torr of Oxygen, 476
Oxidation of Molybdenum 550° to 1700°C, 952
Vapor Pressure of Molybdenum Trioxide, 242
Gunther, W. H. *et al.* Mechanism of the Nickel-Fluorine Reaction, 346

Hackerman, Norman, and Aronowitz, Gerald. Passivity of Iron-Chromium Alloys, 633
Hackerman, Norman, and Ayers, R. C., Jr. Corrosion Inhibition in HCl Using Methyl Pyridines, 507
Hackerman, Norman, and Schmid, G. M. Electrical Double Layer Capacities and Adsorption of Alcohols on Gold, 440
Hackerman, Norman, and Wisdom, N. E., Jr. Surface Studies on Passive Iron, 318
Hackerman, N. *et al.* Introduction to Passivity Symposium Transactions, 596
Hall, R. N. Solubility of III-V Compound Semiconductors in Column III Liquids, 385
Hallenback, J. F., Jr., and Schumann, P. A., Jr. Novel Four-Point Probe for Epitaxial and Bulk Semiconductor Resistivity Measurements, 538
Halsted, R. E., and Lorenz, M. R. High-Purity CdTe by Sealed-Ingot Zone Refining, 343
Hamer, W. J. (ed) The Scope of Electrochemistry, 115C
Hammes, J. P., and Bradley, Arthur. Electrical Properties of Thin Organic Films, 15
Photoconductivity in Thin Organic Films, 543
Hampson, N. A., and Tarbox, M. J. Anodic Behavior of Zinc in Potassium Hydroxide Solution, I. Horizontal Anodes, 95
Hanneken, G. M., Jr., *et al.* Electrodeposition of Nickel-Molybdenum Alloys, 362
Harder, B. R., and Cox, B. Effect of Dissolved Oxygen on the Oxidation of Zircaloy-2 by Steam, 1110
Harper, W. J. Pulse Excitation of Electroluminescent Films of ZnS:Cu(Cl,Br,I), 41
Harrison, D. E., *et al.* New Family of Self-Activated Phosphors, 23
Harrison, R. W., and Delgrosso, E. J. Formation of a Zinc Oxide-Niobium Pentoxide Spinel, 205
Harrop, P. J. (d), 1285
Hayden, H. W., and Brophy, J. H. Activated Sintering of Tungsten with Group VIII Elements, 805
Heine, M. A., and Pryor, M. J. Distribution of A-C Resistance in Oxide Films on Aluminum, 1205
Helpert, E., *et al.* Method for the Preparation of Low-Temperature Alloyed Gold Contacts to Silicon and Germanium. 239
Herrick, C. S., and Tevebaugh, A. D. Oxygen-Controlled Conduction in Thin Films of Cuprous Iodide: A Mixed Valency Anion Semiconductor, 119

Hersch, P. (d), 1284
Heumann, Th., and Panesar, H. S. Contribution to the Electrochemical Behavior of Chromium and Iron-Chromium Alloys in the Transpassive Region, 628
Heusler, K. E. On the Passivity of Manganese in Acid Solutions, 703
Hinton, R. W., *et al.* Effects of Additives on the Structure of Electrodeposited Silver, 103
Hirayama, Chikara. Dissociation Pressure of Zinc Antimonide, 88
Hoar, T. P., and Yahalom, J. Initiation of Pores in Anodic Oxide Films Formed on Aluminum in Acid Solutions, 614
Hoare, J. P. Normal Oxygen Potential on Bright Platinum, 1019
Study of the Rest Potentials in the Gold-Oxygen-Acid System, 245
Hobbs, D. Y., and Ranby, P. W. Thorium Phosphate Phosphors, 280
Hoffman, C. W. W., *et al.* X-Ray Study of Pyrochlore Fluoantimonates of Calcium, Cadmium, and Manganese, 1048
Hoffman, M. V. Systems BaO-MgO-P_2O_5 and BaO-ZnO-P_2O_5 Compounds and Fluorescence, 1223
Holm, G. J., *et al.* Thermodynamics of Hydrocarbon Fuel Cells, 1025
Holschwandner, L. H., and Bergh, A. A. Uniformity of the Wetting and Dissolution of Germanium by Molten Indium, 904
Horne, R. A., *et al.* Effect of Pressure on the Conductivity of Battery Electrolytes, 1282
Horwath, R. S., and Whiteley, C. Extension of Iridium Crucible Lifetime, 467
Hovey, N. W., *et al.* Electrodeposition of Nickel-Molybdenum Alloys, 362
Hovorka, F., *et al.* Electrochemistry of Nickel, II. Anodic Polarization of Nickel, 1007
Electrochemistry of Tin, I. Effects of Nonionic Addition Agents on Electrodeposition from Stannous Sulfate Solutions, 190
Hsiung, Hsiao-shu, and Brown, G. H. Polarography of π-Complexes of Cobalt, Chromium, and Titanium in Formamide and Dimethylformamide, 1085
Huber, Franz. P-N Junction Photovoltaic Effect in Anodically Formed Oxide Films of Titanium, 846
Huber, K. (d), 1286
Hulett, L. D., *et al.* On the Formation of Electrochemical Etch Pits on the (111) Face of Copper, 1190
Hummel, F. A., and Brown, J. J. Phase Equilibria and Manganese-Activated Luminescence in the System $Zn_3(PO_4)_2$-$Cd_3(PO_4)_2$, 1218
Hummel, F. A., and Sarver, J. F. Subsolidus Equilibria and Luminescence Data on Phases in the System MgO-GeO_2-SiO_2-TiO_2, 726
Huq, A. K. M. S. (d), 590, 591
Hurd, R. M., *et al.* Effects of Electrostatic Fields on the Surface Tension of Salt Solutions (d), 590

Ichikawa, Eiichi, *et al.* Electrolytic Reduction of Dicyandiamide. An Experimental Approach to the Difference in Two Courses of Electrolytic Reduction, 918
Indig, M. E., and Snyder, R. N. Lithium Hydride Electrode (d), 590
Sodium Borohydride, an Interesting Anodic Fuel (d), 591
Ing, S. W., Jr., *et al.* Gettering of Metallic Impurities from Planar Silicon Diodes, 533
Low-Temperature Deposition of Silicon Oxide Films, 465
Irvine, W. R., and Lund, J. A. Reaction of Lithium with Water Vapor, 141
Isaacs, H. S., and Leach, J. S. L. Valency Changes in the Surface Oxide Films on Metals, 680
Ives, M. B., and Rosenblatt, G. Adsorption of Iron during Etching of Lithium Fluoride Crystals, 1088

Jaccodine, R. J. Surface Energy of Germanium and Silicon, 524; (d), 1293
Jaffe, P. M. Electroluminescent (Zn,Mg)S:Cu, Halide Phosphors, 979
James, W. J., *et al.* Difference Effect on Magnesium Dissolving in Acids, 1117
Janz, G. J., and Saegusa, Fumihiko. Molten Carbonates as Electrolytes: Viscosity and Transport Properties, 452
Jarry, R. L., *et al.* Mechanism of the Nickel-Fluorine Reaction, 346
Jenkins, L. H., *et al.* On the Formation of Electrochemical Etch Pits on the (111) Face of Copper, 1190
John, H. F., and Faust, J. W., Jr. Growth Twins in the F.C.C. Metals, 463; (d), 1291
Johnson, J. W., *et al.* Difference Effect on Magnesium Dissolving in Acids, 1117
Johnson, K. E., and Laitinen, H. A. Electrochemistry and Reactions in Molten Li_2SO_4-Na_2SO_4-K_2SO_4, 314
Johnson, R. E. Report on the Investigation of Binary System CoS-In_2S_3, 593
Johnston, W. D. Phosphorous Dissociation Pressure over the System $GaP_{(s)}$-$Ga_{(l)}$, 117
Jones, M. E., *et al.* Growth of Crystals from Compounds with Volatile Components, 582
Jorge, L., and Liopis, J. Electrochemical Corrosion of Iridium in Hydrochloric Acid Solutions, 947
Jorgensen, P. J. Effect of an Electric Field on the Oxidation of Zinc, 461
Joyce, B. A., and Bradley, R. R. Epitaxial Growth of Silicon from the Pyrolysis of Monosilane on Silicon Substrates, 1235
Juliard, A. L., and Shalit, Harold. Application of Cyclic Voltammetry to the Kinetic Study of Electro-Oxidation of Organic Compounds, 1002

Kachik, R. H., *et al.* Effect of Alloying Elements on the Oxidation of Tin, 4
Kagetsu, T. J., and Graydon, W. F. Dissolution of Brass in Sulfuric Acid Solutions, II. 95/5 Brass, 709
Kahn, J. S., and Cline, C. F. Microhardness of Single Crystals of BeO and Other Wurtzite Compounds, 773
Kahng, D., *et al.* Epitaxial Silicon Junctions, 394
Impurity Distribution in Epitaxial Silicon Films (c), 393
Karasyk, Leonard, and Linford, H. B. Electrode Kinetic Parameters for Copper Deposition on Clean and Soiled Copper Cathodes, 895
Katan, T., and Galiotto, R. J. Current Efficiencies for the Anodic Oxidation of Ammonia in Potassium Hydroxide Solution, 1022
Kellett, E. A., and Rogers, S. E. Structure of Oxide Layers on Tungsten, 502
Kellogg, H. H. and Duby, Paul. Measurement of "Pressure-EMF" in Pure Fused Salts, 349
Kelly, E. J., *et al.* Electrochemical pH-Stat and Its Application to Corrosion Studies, 1183
Kern, Werner. Zone Refining of Gallium Trichloride. Radiochemical Method for Determining the Distribution of Components in a Column and Its Application in Analyzing the Zone Refining Effectiveness in Purifying Gallium Trichloride, 60
King, C. V. (ed) Chemical Abstracts, 103C; Electrochemical Technology, 3C; Food and Population, 157C; How Long to Boil an Egg, 243C; Las Cucarachas y las Chinches, 229C; Leak Detection, 132C; Plug for our Product, 39C; Woodward Retirement Plan, 83C
King, C. V., *et al.* Ion Exchange on Single-Crystal Silver and Zinc, 1261
King, P. F. Magnesium as a Passive Metal, 1113
Kivel, J., *et al.* Radiochemical Studies of Thioureа in the Electroless Deposition Process, 890
Klamut, C. J., *et al.* Corrosion of Carbon Steel by High-Temperature Liquid Mercury, 964
Klein, D. L., *et al.* Electropolishing Technique for Germanium and Silicon, 412
Klemperer, William. Vibrational Frequencies of the Mercuric Halides, 1023
Klinger, N., *et al.* Reactions Between Refractory Oxides and Graphite, 783
Knight, H. T., *et al.* Porous Tantalum Anodes for Liquid and Solid Electrolytic Capacitors by Reaction in Situ, 12
Knopp, A. N. Some Comments on Thermal Etching of Silicon Surfaces Treated in Sealed Quartz Tubes, 82
Kofstad, Per. Oxidation Behavior of Tantalum at 700°-1000°C, 491
Kofstad, P., and Ruzicka, D. J. On the Defect Structure of ZrO_2 and HfO_2, 181; (d), 1285
Kolb, G. A., and Sullivan, M. V. Chemical Polishing of Gallium Arsenide in Bromine-Methanol, 585
Kolb, G. A., *et al.* Electropolishing Technique for Germanium and Silicon, 412
Kolk, A., and White, H. Magnetic Properties of 97Fe-3 Ni Thin Film Electroplate, 98
Komarek, K. L., *et al.* Reactions Between Refractory Oxides and Graphite, 783
Kozawa, Akiya, *et al.* Electrochemistry of Tin I. Effects of Nonionic Addition Agents on Electrodeposition from Stannous Sulfate Solutions, 190
Kramer, Bernard, and Turner, Alva. Infrared Effects on Luminescence and Conductivity of (UV Excited ZnS Phosphors, 366
Krembs, G. M. Residual Tritiated Water in Anodized Tantalum Films, 938
Kren, J. G., *et al.* Vacuum Evaporation of Cadmium Telluride, 407; (d), 1291
Krikorian, N. H., *et al.* Low-Temperature Thermal Expansion of the Group 4a Carbides, 587
Mutual Solid Solubility of Hafnium Carbide and Uranium Monocarbide, 560
Krohn, Albertine, *et al.* Electrodeposition of Nickel-Molybdenum Alloys, 362
Kronenberg, M. L., *et al.* Electrochemistry of Nickel, II. Anodic Polarization of Nickel, 1007
Kruger, Jerome. Optical Studies of the Formation and Breakdown of Passive Films Formed on Iron Single Crystal Surfaces in Inorganic Inhibitor Solutions, 654
Ku, S.-M. Preparation and Properties of Vapor-Grown GaAs-GaP Alloys, 991
Kuhn, W. E. Formation of Silicon Carbide in the Electric Arc, 298
Kuper, A. B., and Christensen, H. Crystallographic and Electrical Properties of Epitaxial Germanium, 988

LaBotz, R. J., and Mason, D. R. Thermal Conductivities of Mg_2Si and Mg_2Ge, 121
LaBotz, R. J., *et al.* Thermoelectric Properties of Mixed Crystals of $Mg_2Ge_xSi_{1-x}$, 127
Labrie, R. J., and Lamb, V. A. Transference Numbers in Pure Molten Sodium Nitrate, 810
Laendle, K. W., *et al.* Low-Temperature Deposition of Silicon Oxide Films, 465
LaGrange, L. D., *et al.* Electrical Resistivity of Stabilized Zirconia at Elevated Temperatures, 276
Laitinen, H. A., and Johnson, K. E. Electrochemistry and Reactions in Molten Li_2SO_4-Na_2SO_4-K_2SO_4, 314
Laitinen, H. A., and Swofford, H. S., Jr. Electrochemical Investigation of the Reduction of Nitrate in $NaNO_3$-KNO_3 Eutectic at 250°C, 814
Lakshmanan, T. K. Optical and Electrical Properties of Semiconducting Cadmium Oxide Films, 548
Lamb, V. A. and Labrie, R. J. Transference Numbers in Pure Molten Sodium Nitrate, 810
LaQue, F. L. (Presidential Address) Where is the Electrochemical Society Going?, 133C
Larkin, C. F., and Olsen, K. M. Room Temperature Evolution of Hydrogen from High-Purity Nickel, 86
Lauer, G., *et al.* Integration of Single-Sweep Oscillopolarograms, I. Determination of Reactant Adsorption and Oxide Film Reduction at Platinum Electrodes, 926
Leach, J. S. L., (d), 1289
Leach, J. S. L., and Isaacs, H. S. Valency Changes in the Surface Oxide Films on Metals, 680
Lehmann, W. Electroluminescent (Zn,Cd)S: Cu Phosphors, 759
Emission Spectra of (Zn,Cd)S Phosphors, 754
Leja, J., et al. Interferometric Study of Zn/$ZnSO_4$/Zn System, I. Relative Position of Electrodes and Convective Effects, 820
Lever, R. F. Gaseous Equilibrium in the Germanium Iodine System, 775

Liang, C. Y., and Scalco, E. G. Photoconductivities of α and β Forms of Metal-Free Phthalocyanine, 779
Lighty, P. E., and Shanefield, D. Trace Impurity Effects on Growth Hillocks during Epitaxial Electrodeposition from Copper Perchlorate Solutions, 973
Linford, H. B., and Karasyk, Leonard. Electrode Kinetic Parameters for Copper Deposition on Clean and Soiled Copper Cathodes, 895
Littlewood, R. (d), 590
Litz, L. M., and Mercuri, R. A. Oxidation of Boron Carbide by Air, Water, and Air-Water Mixtures at Elevated Temperatures, 921
Llopis, J., and Jorge, L. Electrochemical Corrosion of Iridium in Hydrochloric Acid Solutions, 947
Loch, L. D. Semiconducting Nature of Stannic Oxides, 1081
Loess, R. E., *et al.* Corrosion of 1100 Aluminum in Oxygen-Saturated Water at 70°C, 622
Lorenz, M. R., and Halsted, R. E. High-Purity CdTe by Sealed-Ingot Zone Refining, 343
Lubell, M. S., and Mazelsky, R. Carrier Compensation in Germanium Telluride, 520
Lund, J. A., and Irvine, W. R. Reaction of Lithium with Water Vapor, 141
Luner, Charles, and Murray, M. V. Isolation and Examination of Alloy Layers from Electrolytic Tinplate, 176
Lurie, R. M., *et al.* Ion Exchange Membrane Properties—Their Effect on the Development of the Dual Membrane Fuel Cells, 1173

Mackay, T. L. Oxidation of Zirconium and Zirconium Alloys in Liquid Sodium, 960
Manz, R. C., *et al.* Epitaxial Silicon Junctions, 394
Impurity Distribution in Epitaxial Silicon Films, (c), 393
Marinace, J. C. Diffused Junctions in GaAs Injection Lasers, 1153
Mark, H. B., Jr. Recovery from Polarization of α- and β-PbO_2 in H_2SO_4 Electrolyte, 945
Markby, Raymond, *et al.* Electrochemical Reduction of the Benzene Ring, 425
Mason, D. R., and LaBotz, R. J. Thermal Conductivities of Mg_2Si and Mg_2Ge, 121
Mason, D. R., and O'Kane, D. F. Semiconducting Properties of Peritectic Compounds from the Pseudo-binary System of CdTe-In_2Te_3, 1132
Mason, D. R., *et al.* Phase Diagram for the Pseudo-binary System CdTe-In_2Te_3, 1127
Thermoelectric Properties of Mixed Crystals of $Mg_2Ge_xSi_{1-x}$, 127
Matsen, J. M. Analog Solutions for the Growth of Activation Overpotential, 222
Mayer, S. W., and Brown, W. E., Jr. Electrode Kinetics for Chlorides of Tungsten, Antimony, and Phosphorus, 306
Mazelsky, R., and Lubell, M. S. Carrier Compensation in Germanium Telluride, 520
Mazza, F., and Trassatti, S. Tungsten, Titanium, and Tantalum Carbides and Titanium Nitrides as Electrodes in Redox Systems, 847
McGinnis, L. P., *et al.* Electrode Reactions and Iron Oxide Selection for the Thermal Cell Mg/LiCl-KCl/FeO_x, Ni, 469
McKee, E. S., *et al.* Electrode Reactions and Iron Oxide Selection for the Thermal Cell Mg/LiCl-KCl/FeO_x,Ni, 469
McNeil, M. B. Properties of the Intermetallic Phases in the System Au-Sn, 1169
McNeill, William, and Gruss, L. L. Anodic Film Growth by Anion Deposition in Aluminate, Tungstate, and Phosphate Solutions, 853
Mehl, W., *et al.* Method for the Preparation of Low-Temperature Alloyed Gold Contacts to Silicon and Germanium, 239
Meibuhr, Stuart, *et al.* Electrochemistry of Tin, I. Effects of Nonionic Addition Agents on Electrodeposition from Stannous Sulfate Solutions, 190
Meikleham, V. F., and Glatz, A. C. Preparation and Electrical Properties of Bismuth Trisulfide, 1231
Meissner, H. P., *et al.* Oxygen Transport and Reaction Rates at an Air-Depolarized Copper Cathode (d), 591, 1284
Melamed, N. T., *et al.* New Family of Self-Activated Phosphors, 23
Mercuri, R. A., and Litz, L. M. Oxidation of Boron Carbide by Air, Water, and Air-Water Mixtures at Elevated Temperatures, 921
Meredith, R. E., and Tobias, C. W. Evaluating the Effective Resistances of Diaphragms or Electrolytic Separators, 1257
Merten, U., *et al.* Electrical Resistivity of Stabilized Zirconia at Elevated Temperatures, 276
Meussner, R. A., and Fujii, C. T. Oxide Structures Produced on Iron-Chromium Alloys by a Dissociative Mechanism, 1195
Meyer, R. E. Reduction of Oxygen on Passive Zirconium, 167
Michael, A. B., *et al.* Porous Tantalum Anodes for Liquid and Solid Electrolytic Capacitors by Reaction in Situ, 12
Miles, J. L., and Smith, P. H. Formation of Metal Oxide Films Using Gaseous and Solid Electrolytes, 1240
Miller, C. F., *et al.* Electrical Resistivity of Stabilized Zirconia at Elevated Temperatures, 276
Miller, K. J., and Grieco, M. J. Epitaxial P-Type Germanium and Silicon Films by the Hydrogen Reduction of $GeBr_4$, $SiBr_4$, and BBr_3, 1252
Minamiya, A., *et al.* Effects of an Electric Field on Epitaxial Vapor Growth, 1167
Mooney, R. W., and Schmid, W. F. Thermoluminescence of CaF_2:Mn, 340
Mooney, R. W., *et al.* X-Ray Study of Pyrochlore Fluoantimonates of Calcium, Cadmium, and Manganese, 1048
Morehead, F. F. Dember Effect Study of Shifts in the Stoichiometry of ZnS, 285
Mori, Shiro, *et al.* Corrosion of 1100 Aluminum in Oxygen-Saturated Water at 70°C, 622
Morozumi, T., *et al.* Electrochemical pH-Stat and Its Application to Corrosion Studies, 1183
Morris, L. A., and Smeltzer, W. W. Evaporation of Iron-Chromium Alloys Containing 5 and 25 Per Cent Chromium in the Temperature Range 900°-1080°C, 997
Morrison, R. E., *et al.* Gettering of Metallic Impurities from Planar Silicon Diodes, 533
Mueller, W. A. (d), 592
Mueller, W. A. Throwing Power of the Current in Anodic and Cathodic Protection, 698
Müller, E. K., *et al.* Epitaxial Vapor Deposition of Perovskite Materials, 969
Murray, M. V., and Luner, Charles. Isolation and Examination of Alloy Layers from Electrolytic Tinplate, 176

Nagayama, Masaichi, and Cohen, Morris. Anodic Oxidation of Iron in a Neutral Solution, II. Effect of Ferrous Ion and pH on the Behavior of Passive Iron, 670
Nakata, M. M., and Ervin, Guy, Jr. Oxidation Kinetics of $ZrBe_{13}$ and $NbBe_{12}$, 1103
Newman, R. C., and Wakefield, J. Vapor Growth of Germanium-Silicon Alloy Films on Germanium Substrates, 1068
Newton, Clarence, and Ogburn, Fielding. Relation of Partial (110) Pole Figures to Thickness and Microstructure of Electrodeposited Copper, 1148
Nicholson, B. J., *et al.* Epitaxial Vapor Deposition of Perovskite Materials, 969
Nicholson, H., and Faust, J. W., Jr. Dendritic Growth of InSb, 940
Nickerson, J., *et al.* Influence of Copper on Structural Transformations in ZnS:Cu,Cl, 1228
Nicoll, F. H. Use of Close Spacing in Chemical-Transport Systems for Growing Epitaxial Layers of Semiconductors, 1165
Niedrach, L. W., and Grubb, W. T. High Performance Saturated Hydrocarbon Fuel Cell, 1086

O'Brien, R. N., *et al.* Interferometric Study of Zn/$ZnSO_4$/Zn System, I. Relative Position of Electrodes and Convective Effects, 820
O'Connor, J. J., *et al.* Rapid Neutron Activation Method for Determining Chromium in Ruby Maser and Laser Crystals, 1160
O'Connor, J. R. Phenomena at a Solid-Melt Interface, 338
Odo, Keijiro, *et al.* Electrolytic Reduction of Dicyandiamide. An Experimental Approach to the Difference in Two Courses of Electrolytic Reduction, 918
Ogburn, Fielding, and Newton, Clarence. Relation of Partial (110) Pole Figures to Thickness and Microstructure of Electrodeposited Copper, 1148
Okamoto, Go, and Sato, Norio. Anodic Passivation of Nickel in Sulfuric Acid Solutions, 605
O'Kane, D. F., and Mason, D. R. Semiconducting Properties of Peritectic Compounds from the Pseudo-binary System of CdTe-In_2Te_3, 1132
O'Kane, D. F., *et al.* Thermoelectric Properties of Mixed Crystals of $Mg_2Ge_xSi_{1-x}$, 127
Okura, Kirokuro, *et al.* Effects of an Electric Field on Epitaxial Vapor Growth, 1167
Olsen, K. M., and Larkin, C. F. Room Temperature Evolution of Hydrogen from High-Purity Nickel, 86
Ong, J. N., Jr., *et al.* High-Pressure Oxidation of Metals, Nickel in Oxygen, 185
Osteryoung, R. A., *et al.* Integration of Single-Sweep Oscillopolarograms, I. Determination of Reactant Adsorption and Oxide Film Reduction at Platinum Electrodes, 926
Ozarow, Vernon, *et al.* Photoluminescence of α-SiC, 517

Palilla, F. C., and Rinkevics, M. Field-Induced Luminescence of Powdered Phosphors, 750
Panesar, H. S., and Heumann, Th. Contribution to the Electrochemical Behavior of Chromium and Iron-Chromium Alloys in the Transpassive Region, 628
Patrick, W. J., *et al.* Vacuum Evaporation of Cadmium Telluride, 407 (d), 1291
Pawel, R. E., *et al.* Stress Generation in Tantalum During Oxidation, 551
Paxton, R. R., *et al.* Porous Carbon Gas Diffusion Electrodes, 932
Peakall, K. A., and Antill, J. E. Mechanism of the Oxidation of a Uranium-One Weight Per Cent Copper Alloy, 1146
Pearlstein, F., *et al.* Electrophoretic Deposition of Metals, 843
Pellissier, G. E., *et al.* Effect of Alloying Elements on the Oxidation of Tin, 4
Petersen, R. C., *et al.* Electrochemical Degradation of Aryl Sulfonium Salts, 422
Peterson, E. L., and Balk, P. Properties of HF-H_2O_2 Treated Germanium Surfaces, 1245
Pfahnl, Arnold. Properties of ZnO Phosphors Doped with Li, Ni, and Cu, 381
Phillips, W. L., Jr. Oxidation Rates of Pure and Less Pure Nickel, 1014
Pierret, J. A., *et al.* Porous Tantalum Anodes for Liquid and Solid Electrolytic Capacitors by Reaction in Situ, 12
Pietrzyk, D. J., *et al.* Effect of Electrolyte and Solvent on Polarographic Reductions of Nitrobenzene Derivatives, 995
Pikor, A., *et al.* Some Factors Affecting the Degradation of GaAs Tunnel Diodes, 178
Pizzarello, F. A. Chemical Transport and Epitaxial Deposition of Gallium Arsenide, 1059
Poli, G. (d), 1291
Pompliano, L. A., *et al.* Electropolishing Technique for Germanium and Silicon, 412
Porter, J. T., II, *et al.* Electrical Resistivity of Stabilized Zirconia at Elevated Temperatures, 276
Posey, F. A., *et al.* Electrochemical pH-Stat and Its Application to Corrosion Studies, 1183
Potter, R. M., *et al.* Photoluminescence of α-SiC, 517
Price, R. H., *et al.* Diffusion Coefficients for Hydrogen in β-Zirconium, 799
Pryor, M. J., and Heine, M. A. Distribution of A-C Resistance in Oxide Films on Aluminum, 1205

Queisser, H. J. Properties of Twin Boundaries in Silicon, 52

Ramaswamy, R., *et al.* Electrolytically Regenerated Manganic Sulfate for the Oxidation of Aromatic Hydrocarbons, II. Oxidation of Xylenes to Tolualdehydes, 202
Improvement in the Electrolytic Preparation of Iodoform, 294
Ranby, P. W., and Hobbs, D. Y. Thorium Phosphate Phosphors, 280

Reddy, A. K. N. Relative Corrosion Rates of Nickel Electrodeposits Having Different Textures, 1087
Reid, A. F. Filament Temperatures from Geometry-Independent Electron Emission Functions, 135
Reid, A. F., *et al.* High-Temperature Physical Properties of Carbide-Iodide Thorium, 429
Revesz, A. G. (d), 1292
Rinkevics, M., and Palilla, F. C. Field-Induced Luminescence of Powdered Phosphors, 750
Roe, D. K., and Gerischer, H. Preparation of Spherical Single Crystal Electrodes for Use in Electrocrystallization Studies, 350
Roe, R. M., and Schuldiner, Sigmund. Pt/O_2 Electrode in Sulfuric Acid Solution, 1142
Transition from Hydrogen Ionization to Oxygen Evolution on a Platinum Electrode, 332
Rogers, L. B., *et al.* Effect of Electrolyte and Solvent on Polarographic Reductions of Nitrobenzene Derivatives, 995
Rogers, S. E., and Kellett, E. A. Structure of Oxide Layers on Tungsten, 502
Romano, A. J., *et al.* Corrosion of Carbon Steel by High-Temperature Liquid Mercury, 964
Ropp, R. C. Study of Cadmium Chlorophosphate Phosphor, 113
Rose, G. D., *et al.* Phase Diagram for the Pseudo-binary System CdTe-In_2Te_3, 1127
Rosenblatt, G., and Ives, M. B. Adsorption of Iron during Etching of Lithium Fluoride Crystals, 1088
Rosenblatt, G. M. Interpretation of Knudsen Vapor-Pressure Measurements on Porous Solids, 563
Ross, S. D., *et al.* Electrochemical Degradation of Aryl Sulfonium Salts, 422
Rothschild, S. Coactivator Emission of ZnS and (Zn,Cd)S Phosphors, 28
Rozelle, R. B., *et al.* Porous Carbon Gas Diffusion Electrodes, 932
Rubin, Bernard, *et al.* Rapid Neutron Activation Method for Determining Chromium in Ruby Maser and Laser Crystals, 1160
Rüetschi, Paul. Electrostatic Interaction in the Double Layer, 835
Ruka, R., and Weissbart, J. Solid Electrolyte Fuel Cell (d), 590
Ruzicka, D. J., and Kofstad, P. On the Defect Structure of ZrO_2 and HfO_2, 181; (d), 1285

Saegusa, Fumihiko, and Janz, G. J. Molten Carbonates as Electrolytes: Viscosity and Transport Properties, 452
Sallo, J. S., *et al.* Radiochemical Studies of Thiourea in the Electroless Deposition Process, 890
Salomon, R. E., and Chen, L. C. Anodic Oxidation of Boron, 173
Salomon, R. E., *et al.* Photogalvanic Effects with Anodized Zirconium and Niobium Electrodes, 1163
Sama, D. A., *et al.* Oxygen Transport and Reaction Rates at an Air-Depolarized Copper Cathode (d), 591, 1284
Sampath, S., *et al.* Function of A. C. Superimposed on D. C. in the Anodic Oxidation of Lead in Sulfuric Acid, I
Sarace, J. C., *et al.* Phase Diagram for the Pseudo-binary System CdTe-In_2Te_3, 1127
Sarver, J. F., and Hummel, F. A. Subsolidus Equilibria and Luminescence Data on Phases in the System MgO-GeO_2-SiO_2-TiO_2, 726
Sato, Norio, and Okamoto, Go. Anodic Passivation of Nickel in Sulfuric Acid Solutions, 605
Sautter, F. K. Electrodeposition of Dispersion-Hardened Nickel-Al_2O_3 Alloys, 557
Scalco, E. G., and Liang, C. Y. Photoconductivities of α and β Forms of Metal-Free Phthalocyanine, 779
Schmid, G. M., and Hackerman, Norman. Electrical Double Layer Capacities and Adsorption of Alcohols on Gold, 440
Schmid, G. M., *et al.* Effects of Electrostatic Fields in the Surface Tension of Salt Solutions (d), 590
Schmid, W. F., and Mooney, R. W. Thermoluminescence of CaF_2:Mn, 340
Schmitt, G. A., *et al.* Phase Diagram for the Pseudo-binary System CdTe-In_2Te_3, 1127
Schuldiner, Sigmund, and Roe, R. M. Pt/O_2 Electrode in Sulfuric Acid Solution, 1142
Transition from Hydrogen Ionization to Oxygen Evolution on a Platinum Electrode, 332
Schumann, P. A., Jr., and Hallenback, J. F., Jr. Novel Four-Point Probe for Epitaxial and Bulk Semiconductor Resistivity Measurements, 538
Schwabe, K. Investigation into the Nature of Anodic Passive and Barrier Coatings, 663
Schwartz, L. H., *et al.* Effects of Additives on the Structure of Electrodeposited Silver, 103
Selis, S. M., *et al.* Electrode Reactions and Iron Oxide Selection for the Thermal Cell Mg/LiCl-KCl/FeO_x, Ni, 469
Shalit, Harold, and Juliard, A. L. Application of Cyclic Voltammetry to the Kinetic Study of Electro-Oxidation of Organic Compounds, 1002
Shanefield, D., and Lightly, P. E. Trace Impurity Effects on Growth Hillocks during Epitaxial Electrodeposition from Copper Perchlorate Solutions, 973
Sherfey, J. M. Colorimetric Determination of Half-Cell Entropy Changes, 213
Shimaoka, Goro. Structure of Oxide Films Formed on Individual Crystal Grains of Stainless Steels, 1177
Shirn, G. A., *et al.* Heat-Treatment of Anodic Oxide Films on Tantalum, I. The Effects on Dielectric Properties, 1264
Shtasel, A., *et al.* Porous Tantalum Anodes for Liquid and Solid Electrolytic Capacitors by Reaction in Situ, 12
Sibert, M. E. Electrochemical Oxidation of Titanium Surfaces, 65
Silvester, D. R., *et al.* Influence of Environment on the Corrosion of Zirconium and Its Alloys in High-Temperature Steam, 856
Simkovich, George, and Wagner, J. B., Jr. Influence of Point Defects on the Kinetics of Dissolution of Semiconductors, 513
Simmons, Todd, *et al.* Ion Exchange on Single-Crystal Silver and Zinc, 1261
Singleton, J. H., and Suchow, Lawrence. Effects of Ultraviolet Radiation on Fluorescent Lamp Phosphors, 36
Sligh, J. L., and Brenner, Abner. Galvanostalametry: A New Technique, Based on the Negative Pressure of Liquids, for Investigating Electrochemical Phenomena at an Electrode, 1136
Smeltzer, W. W., and Morris, L. A. Evaporation of Iron-Chromium Alloys Containing 5 and 25 Per Cent Chromium in the Temperature Range 900°-1080°C, 997
Smeltzer, W. W., and Wallwork, G. R. Diffusion of Oxidation in Hafnium, 943
Smialowski, M., and Szklarska-Smialowska, Z. Electrochemical Study of the Nickel-Hydrogen System, 444
Smith, J. T., *et al.*, Electrode Reactions and Iron Oxide Selection for the Thermal Cell Mg/LiCl-KCl/FeO_x,Ni, 469
Smith, P. H., and Miles, J. L. Formation of Metal Oxide Films Using Gaseous and Solid Electrolytes, 1240
Smyth, D. M., and Tripp, T. B. Heat-Treatment of Anodic Oxide Films on Tantalum, II. Temperature Dependence of Capacitance, 1271
Smyth, D. M., *et al.* Heat-Treatment of Anodic Oxide Films on Tantalum, I. The Effects on Dielectric Properties, 1264
Snavely, E. S., Jr., *et al.* Effects of Electrostatic Fields on the Surface Tension of Salt Solutions (d), 590
Snyder, R. N., and Indig, M. E. Lithium Hydride Electrode (d), 590
Sodium Borohydride, an Interesting Anodic Fuel, (d) 591
Spahrbier, D. H., and Cartledge, G. H. Ion-Exchange Properties of the Film on Passive Iron and Steel, 644
Speros, D. M., and Buccilli, P. R. On the Emission of Electrons from Solids in Gas Discharges. II. Accelerating Field Emission, 748
Spiegler, K. S., and Block, M. Transport of Bicarbonate, Carbonate, and Chloride Ions through Ion Exchange Membranes, 577
Stachurski, Z., *et al.* Technique for the Evaluation of Hydrogen Embrittlement Characteristics of Electroplating Baths, 886
Staicopolus, D. N. Role of Cementite in the Acidic Corrosion of Steel, 1121
Steigerwald, R. F., and Greene, N. D. Anodic Dissolution of Binary Alloys (d), 592
Stemple, N. R., and Suchow, Lawrence. New Ternary Semiconducting Compounds, $Cd_4(P,As)_2$ $(Cl,Br,I)_2$, 766
Sternberg, H. W., *et al.* Electrochemical Reduction of the Benzene Ring, 425
Steverding, B. Bond in Heterogeneous Interfaces, 712
Stirland, D. J., and Franklin, R. W. Studies on the Structure of Anodic Oxide Films on Aluminum, II, 262
Stolica, N. D., and Uhlig, H. H. Critical and Passive Current Densities for Copper-Nickel-Zinc Alloys in Sulfuric Acid, 1215
Straumanis, M. E., and Bhatia, B. K. Disintegration of Magnesium While Dissolving Anodically in Neutral and Acidic Solutions, 357
Straumanis, M. E., *et al.* Difference Effect on Magnesium Dissolving in Acids, 1117
Stromatt, R. W. Studies on the Electroreduction of Uranyl (VI) in Molten Equimolar KCl-NaCl by Chronopotentiometric and Electrode Impedance Measurements, 1277
Subbarao, E. C., *et al.* New Family of Self-Activated Phosphors, 23
Suchow, Lawrence, and Singleton, J. H. Effects of Ultraviolet Radiation on Fluorescent Lamp Phosphors, 36
Suchow, Lawrence, and Stemple, N. R. New Ternary Semiconducting Compounds, $Cd_4(P,As)_2$ $(Cl,Br,I)_2$, 766
Sugino, Kiichiro, *et al.* Electrolytic Reduction of Dicyandiamide. An Experimental Approach to the Difference in Two Courses of Electrolytic Reduction, 918
Sullivan, E., *et al.* Effect of Pressure on the Conductivity of Battery Electrolytes, 1282
Sullivan, M. V., and Kolb, G. A. Chemical Polishing of Gallium Arsenide in Bromine-Methanol, 585
Sullivan, M. V., *et al.* Electropolishing Technique for Germanium and Silicon, 412
Sundburg, W. J., and Boddy, P. J. Capacity Measurements on Rapidly Polarized Germanium Electrodes, 1170
Swofford, H. S., Jr., and Laitinen, H. A. Electrochemical Investigation of the Reduction of Nitrate in $NaNO_3$-KNO_3 Eutectic at 250°C, 814
Szklarska-Smialowska, Z., and Smialowski, M. Electrochemical Study of the Nickel-Hydrogen System, 444

Tanaka, John, and Berg, Daniel. Effect of the Dielectric Constant of the Embedding Media on Electroluminescent Light Intensity, 580
Tarbox, M. J., and Hampson, N. A. Anodic Behavior of Zinc in Potassium Hydroxide Solution, I. Horizontal Anodes, 95
Tarui, Y., *et al.* Effects on an Electric Field on Epitaxial Vapor Growth, 1167
Teshima, H., *et al.* Effects of an Electric Field on Epitaxial Vapor Growth, 1167
Tevebaugh, A. D., and Herrick, C. S. Oxygen-Controlled Conduction in Thin Films of Cuprous Iodide: A Mixed Valency Anion Semiconductor, 119
Tevebaugh, A. D., *et al.* Thermodynamics of Hydrocarbon Fuel Cells, 1025
Thirsk, H. R., and Fleischmann, M. Growth of Thin Passivating Layers on Metallic Surfaces, 688
Thomas, C. O., *et al.* Epitaxial Silicon Junctions, 394
Impurity Distribution in Epitaxial Silicon Films, (c) 393
Thomas, J. E., Jr., *et al.* Behavior of Germanium in a Ziegler Electrolyte, 1054
Thomassen, Lars, *et al.* Phase Diagram for the Pseudo-binary System CdTe-In_2Te_3, 1127
Thornton, W. A. Some Aspects of Electroluminescence in ZnS, 370
Tobias, C. W., and Meredith, R. E. Evaluating the Effective Resistances of Diaphragms or Electrolytic Separators, 1257
Trasatti, S., and Mazza, F. Tungsten, Titanium, and Tantalum Carbides and Titanium Nitrides as Electrodes in Redox Systems, 847
Trevethan, D., *et al.* Control of Al Corrosion in Caustic Solutions, 267
Tripp, T. B., and Smyth, D. M. Heat-Treatment of Anodic Oxide Films on Tanta-

lum, II. Temperature Dependence of Capacitance, 1271
Tripp, T. B., *et al.* Heat-Treatment of Anodic Oxide Films on Tantalum, I. The Effects on Dielectric Properties, 1264
Trivich, Dan, *et al.* Behavior of Germanium Electrodes in a Ziegler Electrolyte, 1054
Turner, Alva, and Kramer, Bernard. Infrared Effects on Luminescence and Conductivity of UV Excited ZnS Phosphors, 366
Turner, G. L'E., *et al.* Epitaxial Vapor Deposition of Perovskite Materials, 969

Udupa, H. V. K., *et al.* Function of A.C. Superimposed on D.C. in the Anodic Oxidation of Lead in Sulfuric Acid, 1
Udupa, H. V. K., *et al.* Improvement in the Electrolytic Preparation of Iodoform, 294
Uhlig, H. H., and Stolica, N. D. Critical and Passive Current Densities for Copper-Nickel-Zinc Alloys in Sulfuric Acid, 1215
Uhlig, H. H., *et al.* Corrosion and Passivity of Molybdenum-Nickel Alloys in Hydrochloric Acid, 650
Introduction to Passivity Symposium Transactions, 596

Van Uitert, L. G. Comparison of the Intensities of Emission of Eu^{3+} and Tb^{3+} in Tungstates and Molybdates, 46
Vasudeva Rao, P. V., *et al.* Function of A.C. Superimposed on D.C. in the Anodic Oxidation of Lead in Sulfuric Acid, 1
Vaughn, J. W., and Watt, G. W. Mechanism of Electrodeposition of Metals from Liquid Ammonia Solutions, 723
Venkatachalapathy, M. S., *et al.* Electrolytically Regenerated Manganic Sulfate for the Oxidation of Aromatic Hydrocarbons, II. Oxidation of Xylenes to Tolualdehydes, 202
Improvement in the Electrolytic Preparation of Iodoform, 294
Vermilyea, D. A. Flaws in Anodic Ta_2O_5 Films, 205; (d), 1286
Stresses in Anodic Films, 345; (d), 1289
Vetter, K. J. General Thermodynamic Theory of the Potential of Passive Electrodes and Its Influence on Passive Corrosion, 597
Victor, George, and Duke, F. R. Transport Numbers of Some Pure Fused Nitrates and Nitrites, 91
Vijayavalli, R., et al. Function of A.C. Superimposed on D.C. in the Anodic Oxidation of Lead in Sulfuric Acid, 1
Viklund, Hans, *et al.* Ion Exchange Membrane Properties—Their Effect on the Development of the Dual Membrane Fuel Cells, 1173

Wagenknecht, J. H., and Wawzonek, S. Polarographic Studies in Acetonitrile and Dimethylformamide, VII. The Formation of Benzyne, 420
Wagner, Carl, and Werner, Alfred. Role of Displacement Reactions in the Determination of Activities in Alloys with the Aid of Galvanic Cells, 326
Wagner, J. B., Jr., and Simkovich, George. Influence of Point Defects on the Kinetics of Dissolution of Semiconductors, 513
Wajszel, Dominik. Method for Calculating Paralinear Constants for the Formation of Volatile Scale, 504
Wakefield, J., and Newman, R. C. Vapor Growth of Germanium-Silicon Alloy Films on Germanium Substrates, 1068
Wales, R. D. Anodic Formation of Germanium Oxidic Films, 914
Power Supply for Currents of 200 Microamperes or Less, 946
Wallace, T. C., *et al.* Low-Temperature Thermal Expansion of the Group 4a Carbides, 587
Wallwork, G. R., and Smeltzer, W. W. Diffusion of Oxygen in Hafnium, 943
Wanklyn, J. N. (d), 1285
Wanklyn, J. N., *et al.* Influence of Environment on the Corrosion of Zirconium and Its Alloys in High-Temperature Steam, 856
Watanabe, Akira. A-C Methods in Interfacial Electrical Phenomena, 72
Watt, G. W., and Cunningham, J. A. Mechanism of Electrodeposition from Aqueous Solutions of Square Planar Complexes, 716
Watt, G. W., and Vaughn, J. W. Mechanism of Electrodeposition of Metals from Liquid Ammonia Solutions, 723
Wawzonek, S., and Wagenknecht, J. H. Polarographic Studies in Acetonitrile and Dimethylformamide, VII. The Formation of Benzyne, 420
Weber, H. C., *et al.* Oxygen Transport and Reaction Rates at an Air-Depolarized Copper Cathode (d) 591, 1284
Well, K. G. Influence of Film Thickness on the Thermodynamic Properties of Thin Oxide Layers on Iron, 640
Weiner, J. R., *et al.* Rapid Neutron Activation Method for Determining Chromium in Ruby Maser and Laser Crystals, 1160
Weininger, J. L., and Breiter, M. W. Effect of Crystal Structure on the Anodic Oxidation of Nickel, 484
Weinreich, O. A. Antireflection Films on GaAs Electroluminescent Diodes, 1124
Weinstein, Martin, and Elliott, J. F. Thermodynamic Properties of the Manganese-Lead-Bismuth System, 792
Weisberg, L. R., and Celmer, P. R. Arsenic Purification by Crystal Growth from the Melt, 56
Weissbart, J., and Ruka, R. Solid Electrolyte Fuel Cell (d), 590
Wender, Irving, *et al.* Electrochemical Reduction of the Benzene Ring, 425
Werner, Alfred, and Wagner, Carl. Role of Displacement Reactions in the Determination of Activities in Alloys with the Aid of Galvanic Cells, 326
Whalen, J. J. Graphical Method for Determining the Broad-Band Dielectric Behavior of Materials, 1015
White, H., and Kolk, A. Magnetic Properties of 97 Fe-3 Ni Thin Film Electroplate, 98
Whiteley, C., and Horwath, R. S. Extension of Iridium Crucible Lifetime, 467
Whitmore, D. H., and Blumenthal, R. N. Thermodynamic Study of Phase Equilibria in the Titanium-Oxygen System within the $TiO_{1.00}$-TiO_2 Region, 92
Wick, R., *et al.* Electrophoretic Deposition of Metals, 843
Wilkins, N. J. M., *et al.* Influence of Environment on the Corrosion of Zirconium and Its Alloys in High-Temperature Steam, 856
Will, F. G. Electrochemical Oxidation of Hydrogen on Partially Immersed Platinum Electrodes, I. Experiments and Interpretation, 145; II. Theoretical Treatment, 152
Williams, K. R., and Gregory, D. P. Electrolytes for Low-Temperature Fuel Cells, 209
Wilmhurst, R. E., *et al.* High-Temperature Physical Properties of Carbide-Iodide Thorium, 429
Wilson, O., *et al.* Growth of Crystals from Compounds with Volatile Components, 582
Wisdom, N. E., Jr., and Hackerman, Norman. Surface Studies on Passive Iron, 318
Witteman, W. G., *et al.* Mutual Solid Solubility of Hafnium Carbide and Uranium Monocarbide, 560
Wolf, E. D., and Duke, F. R. Transference Numbers and Ion Association in Pure Fused Alkaline Earth Chlorides, 311
Wolff, G. A. (d), 1293
Wolff, G. A. and Broder, J. D. New Method of GaP Growth, 1150
Wood, G. B. Study of Embrittlement of High Strength Steels by Hydrogen Isotopes, I. Testing of Steel Rings as Specimens, a Comparison of Hydrogen and Deuterium Embrittlement, and Permeation Studies, 867; II. A Comparison of Gas Contents and Hydrogen or Deuterium Embrittlement Resulting from Electroplating Processes, 877
Wylie, A. W. *et al.* High-Temperature Physical Properties of Carbide-Iodide Thorium, 429

Yahalom, J., and Hoar, T. P. Initiation of Pores in Anodic Oxide Films Formed on Aluminum in Acid Solutions, 614
Yakymyshyn, W. F., *et al.* Interferometric Study of Zn/$ZnSO_4$/Zn System, I. Relative Position of Electrodes and Convective Effects, 820
Yeager, E., *et al.* Electrochemistry of Nickel, II. Anodic Polarization of Nickel, 1007
Yeager, Ernest, *et al.* Electrochemistry of Tin, I. Effects of Nonionic Addition Agents on Electrodeposition from Stannous Sulfate Solutions, 190
Yeh, T. H. Surface Masking in Gallium Arsenide During Diffusion, 341
Yeh, T. H., and Blakeslee, A. E. Junction Delineation in Gallium Arsenide, 1018
York, D. B. Properties of Evaporated Thin Films of SiO, 271
Young, G. J., et al. Porous Carbon Gas Diffusion Electrodes, 932
Young, L. Condenser Pressure as an Explanation of Field Dependent Tafel Slopes of High Field Ionic Conduction of Anodic Tantalum Pentoxide Films, 589

Zaininger, K. H. (d), 1292
Zaromb, Solomon. Geometric Requirements for Uniform Current Densities at Surface-Conductive Insulators or Resistive Electrodes (c), 271
Theory and Design Principles of the Reversible Electroplating Light Modulator (c) 271
Zaromb, S., *et al.* Control of Al Corrosion in Caustic Solutions, 267
Zubler, E. G. Gettering Properties of Tantalum, 1072

Subject Index (Vol. 110, 1963)

d Indicates Discussion

ed Indicates Editorial

Acetonitrile. Polarographic studies. 420
Acidity. Control by pH-stat. 1183
See also pH
Activity. Alloys. Determination. 326
Addition agent
Nonionic. Electrodeposition of tin. 190
Organic. Electrodeposition of silver. 103
Adsorption
Alcohols on gold. 440
Anion. Oxidation of ethylenediaminetetraacetocobalt (II). 436
Aromatic hydrocarbons at gold electrolyte interface. 1075
Iron during etching of lithium fluoride. 1088
Kinetics. Oxidation of methanol. 449
Reactant. From triiodide solutions. 926
See also Ion exchange
Alcohols
Adsorption on gold. 440
See also Methanol
Alkali carbonates. As electrolytes. Viscosities and transport properties. 452
Alkali nitrates
Transport numbers. 91
See also Potassium nitrate. Sodium nitrate
Alkali nitrites. Transport numbers. 91
Alkaline earth chlorides. Transference numbers and ion association. 311
Alloy
Activities. Determination by displacement reactions. 326
Aluminum. Corrosion. 622
Aluminum oxide-nickel. *See* Nickel-aluminum oxide, *below*
Binary. Anodic dissolution. *d*. 592
Brass. Dissolution. 709
Chromium-iron. *See* Iron-chromium, *below*
Copper-nickel-zinc. Current densities. 1215
Copper-uranium. *See* Uranium-copper, *below*
Effect on oxidation of tin. 4
Gallium arsenide-gallium phosphide. Preparation and properties. 991
Germanium-silicon. Films. Vapor growth. 1068
Iron-chromium
Behavior in transpassive region. 628
Evaporation. 997

Oxide structures. 1195
Passivity. 633
Iron-nickel. Magnetic properties. 98
Molybdenum-nickel. Corrosion and passivity. 650
See also Nickel-molybdenum, *below*
Nickel-aluminum oxide. Electrodeposition. 557
Nickel-iron. *See* Iron-nickel, *above*
Nickel-molybdenum.
Electrodeposition. 362
See also Molybdenum-nickel, *above*
Nickel-zinc-copper. *See* Copper-nickel-zinc, *above*
Silicon-germanium. *See* Germanium-silicon, *above*
Tin. Layers isolated from tinplate. 176
Uranium-copper. Oxidation. 1146
Zinc-copper-nickel. *See* Copper-nickel-zinc, *above*
Zircaloy-2
Corrosion. 856
Oxidation by steam. 1110
Zirconium
Corrosion. Influence of environment. 856
Oxidation in liquid sodium. 960
Aluminates. Anion deposition. 853
Aluminum
Alloys. Corrosion. 622
Anodic oxide films. Structure. 262
Corrosion. Control in caustic solutions. 267
Growth twins. 463, *d.* 1291
Oxide films. Distribution of a-c resistance. 1205
Aluminum oxide
Anodic film.
Initiation of pores. 614
Structure. 262
See also Nickel-aluminum oxide alloys
Ammonia
Anodic oxidation. Current efficiencies. 1022
Electrodeposition of metals. 723
Analog computer. Study of activation overpotential. 222
Anion
Adsorption. Oxidation of ethylenediaminetetraacetocobalt (II). 436
Deposition. For anodic film growth. 853
Anisotropy. *See* Optical anisotropy
Anode
Tantalum. Prepared in situ. 12
Zinc. In potassium hydroxide. 95
See also Dissolution, Anodic. Films, Anodic. Oxidation, Anodic. Polarization, Anodic
Anodic coatings. 663
Anodic films
Aluminum. 262, 614
Growth by anion deposition. 853
Stresses. 345, *d.* 1289
Tantalum pentoxide
Flaws. 250, *d.* 1286
Heat treatment. 1264, 1271
Ionic conduction. 589
Anodic oxidation
Ammonia. Current efficiencies. 1022
Boron. 173
Germanium. 914
Iron. Effect of ferrous ion and pH. 670
Lead. 1
Methanol on platinum. Adsorption kinetics. 449
Nickel. Effect of crystal structure. 484
Spectroscopy studies. 849
Titanium. 65
Anodic passivation. Nickel. 605
Anodic protection. Throwing power of current. 698
Antimonates. *See* Pyrochlore fluoantimonates
Antimonides. *See* Indium antimonide. Zinc antimonide
Antimony chlorides. Electrode kinetics. 306
Arsenic. Purification by crystal growth. 56
Arsenides. *See* Gallium arsenide. Indium arsenide
Aryl sulfonium salts. Electrochemical degradation. 422
Autodoping. Germanium in epitaxial films. 1065

Barium oxide-magnesium oxide-phosphorus pentoxide system. Fluorescence. 1223
Barium oxide-zinc oxide-phosphorus pentoxide system. Fluorescence. 1223
Barrier coating. 663
Battery.
Ancient. *ed.* 211C
Electrolytes. Effect of pressure. 1282
See also Leclanché battery
Benzene. Electrochemical reduction. 425
Benzyne. Formation. Polarographic studies. 420
Beryllides. *See* Niobium beryllide. Zirconium beryllide
Beryllium oxide. Microhardness. 773
Bismuth. *See* Manganese-lead-bismuth system
Bismuth trisulfide. Preparation and electrical properties. 1231
Boiling of eggs. *ed.* 243C
Bond. In heterogeneous interfaces. 712
Book reviews. 14C, 31C, 76C, 96C, 121C, 205C, 238C, 251C, 271C
Borohydrides. *See* Sodium borohydride
Boron. Anodic oxidation. 173
Boron carbide. Oxidation. 921
Brass. Dissolution in sulfuric acid. 709
Bromides. *See* Silicon tetrabromide

Cadmium chloride. In formation of cadmium chlorophosphate phosphor. 113
Cadmium chlorophosphate phosphor. 113
Cadmium oxide. Films. Properties. 548
Cadmium phosphate. *See* Zinc phosphate-cadmium phosphate system
Cadmium sulfide
Effect on electroluminescence of zinc sulfide phosphors. 1045
Evaporated films. X-ray study. 1083
Microhardness. 773
Photoconductivity. 456
See also Zinc telluride-cadmium sulfide heterojunctions
Cadmium telluride
High-purity by zone refining. 343
Vacuum evaporation. 407, *d.* 1291
Cadmium telluride-indium telluride system
Phase diagram. 1127
Semiconducting properties. 1132
Calcium fluoride-manganese phosphor. 340
Calcium halophosphates. Color center formation. 374, 1230
Calorimetry. Determination of half-cell entropy changes. 213
Capacitor
Electrolytic. Tantalum anodes. 12
Silicon dioxide. Thin film. 361
Capacity measurement
Germanium electrodes. 1170
Carbides. *See* Boron carbide. Cementite. Hafnium carbide. Silicon carbide. Tantalum carbide. Titanium carbide. Tungsten carbide. Uranium monocarbide. Zirconium carbide
Carbon. Porous gas diffusion electrodes. 932
See also Graphite. Steel, Carbon
Carbonates
Molten, as electrolytes. Viscosities and transport properties. 452
See also Alkali carbonates
Carrier compensation. In germanium telluride. 520
Cathode
Copper
Kinetics. 895
Oxygen transport. *d.* 591
See also Polarization, Cathodic
Cathodic protection
Throwing power of current. 698
See also Corrosion
Cathodoluminescence. Zinc phosphate-cadmium phosphate system. 1218
Cell. *See* Fuel cell. Galvanic cell. Knudsen cell. Leclanche cell. Thermal cell
Cementite. Acidic corrosion of steel. 1121
"Chemical Abstracts". *ed.* 103C
Chlorides. See Alkaline earth chlorides. Antimony chlorides. Cadmium chloride. Gallium trichloride. Lead chloride. Phosphorus chlorides. Tungsten hexachloride
Chromium
Behavior in transpassive region. 628
Determination in ruby. 1160
See also Iron-chromium alloys. Pi-complexes of chromium
Chronopotentiometry
Drawback in technique. 926
Measurement of electrode kinetics. 306
Study of passivity of iron-chromium alloys. 633
Study of uranyl (VI) electroreduction. 1277
Surface studies of passive iron. 318
Close spacing. Growth of epitaxial layers. 1165
Coactivator. Emission of zinc sulfide phosphors. 28
Coating. Anodic passive and barrier. 663
Cobalt. *See* Pi-complexes of cobalt
Cobalt sulfide-indium sesquisulfide system. 393
Color centers. Formation in calcium halophosphates. 374, *c.* 1230
Computers. *See* Analog computer
Conduction. Oxygen-controlled. 119
Conductivity. *See* Electrical conductivity. Photoconductivity. Thermal conductivity
Copper
Cathode
For copper electrodeposition. 895
Oxygen transport. *d.* 591
Electrodeposited
Impurity effects. 973
Structure and thickness. 1148
Etch pits on (111) face. 1190
Growth twins. 463, *d.* 1291
Influence on zinc sulfide phosphors. 1229
See also Uranium-copper alloy
Copper-nickel-zinc alloys. Current densities. 1215
Corrosion
Aluminum
Control in caustic solutions. 267
In oxygen-saturated water. 622
Carbon steel. By liquid mercury. 964
Electrochemical. Of iridium. 947
Inhibition. Of iron with methyl pyridines 507
Iridium in hydrochloric acid. 947
Molybdenum-nickel alloys. 650
Nickel electrodeposits. 1087
Passive. Effect of potential. 597
Steel. Role of cementite. 1121
Studies with pH-stat. 1183
Crystal
Arsenic. Purification. 56
Ruby maser and laser. Chromium determination. 1160
Silicon. Twin boundaries. 52
Crystal growth
Arsenic. For purification. 56
Compounds with volatile components. 582
Dendritic. Indium antimonide. 940
Gallium phosphide. New method. 1150
Impurity effects on growth hillocks. 973
Phenomena at solid-melt interface. 338
See also Growth twins
Crystal structure.
Effect on oxidation of nickel. 484
See also Microhardness
Cuprous iodide. Conduction. Oxygen-controlled. 119
Current
Alternating
Distribution of resistance in aluminum oxide films. 1205
Methods in interfacial phenomena. 72
Superimposed on d-c in lead oxidation. 1
Densities. For copper-nickel-zinc alloys. 1215
Efficiencies. For oxidation of ammonia. 1022
Power supply. 946
Throwing power. 698
Cyclic voltammetry. In electro-oxidation study. 1002

Defect structure. Of hafnium and zirconium dioxides. 181, *d.* 1285
Degradation
Gallium arsenide tunnel diodes. 178
See also Electrochemical degradation
Dember effect. Zinc sulfide. 285
Deposition
Low-temperature. Silicon dioxide films. 465
See also Anion deposition. Electrodeposition. Electroless deposition. Electrophoretic deposition. Epitaxial deposition. Pyrolytic deposition
Deuterium. *See* Hydrogen, Isotopes
Diaphragm. Resistance. Effectiveness. 1257
Dicyandiamide. Electrolytic reduction. 918
Dielectric. Silicon dioxide. 361
Dielectric constant
Embedding media. Electroluminescent light intensity. 580
Graphical method for determination. 1015
Difference effect. Magnesium in acid solution. 1117
Diffraction. X-ray. Cadmium sulfide. 1083
Diffusion
Coefficients for hydrogen in zirconium. 799
Oxygen in hafnium. 943
Porous carbon electrodes. 932
Dimethylformamide
Polarography. 1085
Formation of benzyne. 420
Reduction of ethenes. 231

Solvent for electrochemical degradation. 422
Diode
Gallium arsenide. 1124
Silicon. Gettering of impurities. 533
See also Tunnel diodes
Displacement reactions. Alloy activities. 326
Dissociation pressure
Gallium phosphide. 117
Zinc antimonide. 88
Dissolution
Anodic. Of binary alloys. *d.* 592
Brass in sulfuric acid. 709
Germanium by indium. 904
Iridium. 947
Magnesium
In acids. Difference effect. 1117
In neutral and acid solutions. 357
Metal monolayers. Kinetics. 1035
Platinum oxide films. 826
Semiconductors. Point defects. 513
Doping
Zinc oxide phosphors. 381
See also Autodoping

Electric arc. Formation of silicon carbide. 298
Electric field
Effect on epitaxial growth. 1167
Effect on oxidation of zinc. 461
Electrical conductivity
Battery electrolytes. 1282
Cuprous iodide. Effect of oxygen. 119
Perylene-metal halide complexes. 769
Thin organic films. 15
See also Semiconductor
Electrical resistivity. Zirconia. 276
Electrochemical degradation. Aryl sulfonium salts. 422
Electrochemical oxidation
Hydrogen. 145, 152
Titanium surfaces. 65
Electrochemical reaction. Simultaneous discharge of metal ions. 1030
Electrochemical reduction. Benzene. 425
Electrochemical Society
Annual reports. 140C
Awards
Acheson Medal. 250C, 269C
William Blum. 27C
Fink Summer Fellowship. 90C
Summer Fellowships. 27C, 89C, 90C, 145C, 250C, 270C
Turner Memorial. 145C
Weston Summer Fellowship. 90C
Young Authors' Prize. 145C
Division news
Battery. 91C, 248C
Corrosion. 10C
Electrodeposition. 28C
Electronics. 76C, 91C, 141C, 266C
Electrothermics and Metallurgy. 91C, 123C, 202C
Industrial Electrolytic. 219C
Officers. 236C
Theoretical Electrochemistry. 28C, 146C
Divisional structure. *ed.* 115C
"Electrochemical Technology." *ed.* 3C, 8C
Growth and direction (Presidential Address). 133C
Journal. Page charge. *ed.* 257C
National meetings. Omission of reference to specific products. *ed.* 39C
Obituaries
Erik A. Blomgren. 250C
Thomas D. Callinan. 237C
Leo Cavallaro. 237C
Guilliam H. Clamer. 125C
Allan T. Gwathmey. 149C
Paul H. Keck. 126C
Ethel Kramberg. 107C
Milo W. Krejce. 238C
Oliver W. Storey. 126C, 150C
Frank E. W. Wetmore. 96C
Publications. *ed.* 3C, 8C, *ed.* 21C
Section news
Boston. 199C
Chicago. 29C, 266C
Cleveland. 11C, 219C
Columbus. 201C, 249C
Detroit. 146C, 201C
India. 11C, 146C
Indianapolis. 29C, 92C
Mohawk-Hudson. 11C, 29C, 92C
Officers. 235C
Ontario-Quebec. 29C, 146C
Pittsburgh. 29C, 201C
San Francisco. 236C, 249C
Southern California-Nevada. 106C, 219C, 249C
"Electrochemical Technology." *ed.* 3C, 8C
Electrochemistry
Chromium and iron-chromium alloys. 628
Lithium sulfate-sodium sulfate-potassium sulfate. 314
Nickel. Anodic polarization. 1007
Nickel-hydrogen system. 444
Organic sulfur compounds. 353
Pyridine. Polarography. 160
Scope. *ed.* 115C
Tin. Effect of additives. 190
See also Battery. Cell
Electrocrystallization. Single crystal electrodes. 350
Electrode
Carbides and nitrides. Redox systems. 847
Germanium
Capacity measurements. 1170
In Ziegler electrolyte. 1054
Iridium. Passivation. 947
Iron oxides on nickel in thermal cell. 469
Kinetics
Copper deposition. 895
Tungsten, antimony, and phosphorus chlorides. 306
Lithium hydride. *d.* 590
Metal. Zero charge point. 466
Niobium. Photogalvanic effects. 1163
Platinum
Electrochemical oxidation of hydrogen. 145, 152
Hydrogen ionization-oxygen evolution. 332
Passive. Potential. 597
Platinum-oxygen in sulfuric acid. 1142
Porous gas diffusion. 932
Single crystal. Preparation. 350
Zirconium. Photogalvanic effects. 1163
See also Anode. Cathode
Electrodeposition
Copper
From perchlorate solutions. 973
Kinetics. 895
Structure. 1148
Metal monolayers. Kinetics. 1035
Metals from ammonia. 723
Nickel. Corrosion rates. 1087
Nickel-aluminum oxide alloys. 557
Nickel-molybdenum alloys. 362
Planar complexes. Mechanism. 716
Silver. Effect of additives. 103
Tin. Effect of additives. 190
See also Electroplating
Electroless deposition. Nickel. 890
Electroluminescence
Effect of dielectric constant. 580
Zinc-cadmium sulfide phosphors. 759
Zinc-magnesium sulfide phosphors. 979
Zinc sulfide. Phosphors. 370
Effect of cadmium sulfide. 1045
Pulse excitation. 41
Zinc sulfide powder particles. 733
Electrolysis
Macroscale. Of inorganic salts. 160
See also Ion
Electrolyte
Battery. Effect of pressure. 1282
Effect of ferro-ferricyanide system. 237
Gold. Adsorption of hydrocarbons. 1075
Low-temperature fuel cells. 209
Solid fuel cell. *d.* 590
Ziegler. Germanium electrodes. 1054
Electrolytic separators. *See* Diaphragm
Electromotive force
"Pressure-emf" measured in fused salts. 349
See also Polarography
Electron emission
From solids. 748
Functions. To define filament temperatures. 135
Electro-oxidation.
Ethylenediaminetetraacetocobalt (II). 436
Organic compounds. Kinetics. 1002
Electrophoretic deposition. Metals. 843
Electroplating
Hydrogen embrittlement. 877,886
Iron-nickel thin film. Magnetism. 98
Electropolishing. Germanium and silicon. 412
Electroreduction. Uranyl (VI). 1277
Electrostatic field. Effect on surface tension of salt solutions. *d.* 590
Electrostatics. In the double layer. 835
Embrittlement
Hydrogen. 867, 877, 886
Steel. 867, 877
Emission
Coactivator. Zinc sulfide phosphors. 28
Intensities. Europium and terbium ions. 46
Of electrons. For determination of filament temperatures. 135
Spectra. Zinc sulfide-type phosphors. 754
Energy. *See* Surface energy
Entropy. Half-cell changes. Calorimetry. 213
Epitaxial deposition
Gallium arsenide. 1059
Perovskites. 969
Epitaxial films. Germanium and silicon. 1252
Epitaxial growth
Effects of electric field. 1167
Gallium arsenide. Rates. 588
Germanium. Kinetic theory. 1065
Silicon from pyrolysis of silane. 1235
Zinc telluride-cadmium sulfide heterojunctions. 410
Epitaxial junctions
Silicon. 394
Zinc telluride-cadmium sulfide. 401
Epitaxial layers. Close spacing. 1165
Epitaxial structure. Resistivity. Probe. 538
Equilibrium
Gaseous. Germanium-iodine system. 775
Subsolidus. Magnesium oxide-germanium oxide-silicon dioxide-titanium dioxide system. 726
See also Phase equilibrium
Etching
Electrochemical. Pits on copper. 1190
Lithium fluoride. Adsorption of iron. 1088
Thermal
Iron-chromium alloys. 997
Silicon surfaces. 82
Ethenes. Polarographic reduction. 225, 231
Ethylenediaminetetraacetocobalt (II).
Electro-oxidation. 436
Europium molybdates and tungstates. Emission intensities. 46
Evaporation.
Iron-chromium alloys. 997
See also Vacuum evaporation
Expansion. *See* Thermal expansion

Ferro-ferricyanide system. Effect of electrolytes on transfer coefficient. 237
Ferrous ion. Effect on passive iron. 670
Filament. Vapor-deposited. Temperature from electron emission functions. 135
Film
Aluminum oxide. Structure. 262
Anodic. Stresses. 345
Antireflection. Gallium arsenide diodes. 1124
Cadmium oxide. Properties. 548
Cadmium sulfide. X-ray diffraction. 1083
Cadmium telluride. Properties. 407
Cuprous iodide. Conductivity. 119
Epitaxial germanium. Properties. 988
Formation. Optical studies. 654
Germanium-silicon. Vapor growth. 1068
Growth by anion deposition. 853
Ion-exchange properties. 644
Iron-nickel electroplate. Magnetism. 98
Iron oxide layers. Effect of thickness. 640
Iron single crystal surfaces. 654
Lithium hydroxide. Formation. 141
Metal oxides. Valency changes. 680
Organic polymer
Electrical properties. 15
Photoconductivity. 543
Prepared by glow discharge process. 15, 543
Passive. Formation on iron crystals. 654
Passive iron and steel. 644
Platinum oxide. Formation. 826
Silicon dioxide. Pyrolytic deposition. 361
Silicon oxide.
Low-temperature deposition. 465
Vacuum deposition. 271
Tantalum. Residual water. 938
Tantalum pentoxide. Flaws. 250, *d.* 1286
See also Anodic film. Epitaxial film. Oxide film
Flaws. Anodic tantalum pentoxide films. 250, *d.* 1286
Fluorescence
In barium oxide-magnesium oxide-phosphorus pentoxide and barium oxide-magnesium oxide-phosphorus pentoxide systems. 1223
See also Electroluminescence. Phosphor
Fluorescent lamp. Phosphors irradiated by mercury arc. 36
Fluorides
See Calcium fluoride. Hydrogen fluoride. Lithium fluoride
Fluorine. Reaction with nickel. 346
Food and population. *ed.* 157C
Force. *See* Electromotive force
Formamide. Polarography. 1085
Frequencies. *See* Vibrational frequencies
Fuel cell
Hydrocarbon
Saturated. 1086

Thermodynamics. 1025
Ion exchange membrane. 1173
Liquid-metal. 1097
Low-temperature. Electrolytes. 209
Propane. 1086
Regenerable. Polyvalent halides. 306
Sodium borohydride. d. 591
Solid electrolyte. d. 590
Thermally regenerative. 1097

Gallium arsenide
Chemical polishing. 585
Chemical transport. 1059
Crystal growth. 582
Diodes. Antireflection films. 1124
Epitaxial deposition. 1059
Growth rates. 588
Junction delineation. 1018
Lasers. Diffused junctions. 1153
Surface masking during diffusion. 341
Tunnel diodes. Degradation. 178
Gallium arsenide-gallium phosphide alloys. Vapor grown. Preparation. 991
Gallium-group V semiconductors. Solubility in gallium. 385
Gallium phosphide
Dissociation pressure. 117
New method of growth. 1150
See also Gallium arsenide-gallium phosphide alloys
Gallium trichloride. Zone refining. 60
Galvanic cell. Measurement of activity. 326
Galvanostalametry. Technique for investigating electrode phenomena. 1136
Germanides. *See* Magnesium germanide
Germanium
Autodoping. Kinetic theory. 1065
Dissolution by indium. 904
Electrodes
Capacity measurements. 1170
In Ziegler electrolyte. 1054
Electropolishing. 412
Epitaxial
Crystallographic and electrical properties. 988
Films. 1252
Gold plating. 239
Interface with aqueous electrolyte. 570
Overspread by indium. 908
Surface energy. 524, d. 1293
Surface treatment with hydrogen fluoride-hydrogen peroxide. 1245
Vapor phase epitaxial growth. 1065
Wetting by indium. 904
Germanium dioxide.
Films. Anodic formation. 914
See also Magnesium oxide-germanium dioxide-silicon dioxide-titanium dioxide system
Germanium-iodine system. Gaseous equilibria. 775
Germanium-silicon alloys. Films. 1068
Germanium telluride. Carrier compensation. 520
Gettering
Impurities from silicon diodes. 533
Properties of tantalum. 1072
Glow discharge polymerization. 15, 543
Gold
Adsorption
Alcohols. 440
Aromatic hydrocarbons. 1075
Contacts to silicon and germanium. 239
Gold-oxygen-acid system. Rest potentials. 245
Gold stannides. Properties. 1169
Graphite
Oxidation. 476
Reactions with refractory oxides. 783
Growth. *See* Crystal growth. Epitaxial growth. Vapor growth
Growth twins. In lead, copper and aluminum. 463, d. 1291

Hafnium. Diffusion of oxygen. 943
Hafnium carbide.
Solubility with uranium monocarbide. 560
Thermal expansion. 587
Hafnium dioxide. Defect structure. 181, d. 1285
Halides. See Bromides. Chlorides. Fluorides. Iodides. Mercuric halides
Halogens. *See* Fluorine. Iodine
Halophosphates
Calcium. Formation of color centers. 374, 1230
Ultraviolet radiation. 36
Hydrides. *See* Borohydrides. Lithium hydride
Hydrocarbons
Aromatic
Adsorption by gold electrolyte. 1075
Oxidation by manganic sulfate. 202
Fuel cells
Saturated. 1086
Thermodynamics. 1086
See also Propane
Hydrogen
Embrittlement. 867, 877, 886
Evolution from nickel. 86
Ionization of platinum electrodes. 332
Isotopes. Embrittlement of steel. 867, 877
Oxidation on platinum electrodes. 145, 152
Sorption on platinum. 332
Zirconium. Diffusion coefficients. 799
Hydrogen fluoride-hydrogen peroxide. Treatments of germanium surfaces. 1245
Hydroxides. *See* Lithium hydroxide

Impedance
Electrode. Electroreduction of uranyl (VI). 1277
Leclanché cells and batteries. 1091
See also Resistance
Indium
Dissolution and wetting of germanium. 904
Spreading over germanium. 908
Indium antimonide. Dendritic growth. 940
Indium arsenide. Crystal growth. 582
Indium-group V semiconductors. Solubility in indium. 385
Indium sesquisulfide. *See* Cobalt sulfide-indium sesquisulfide system
Indium telluride. *See* Cadmium telluride-indium telluride system
Infrared radiation. Effect on zinc sulfide phosphors. 366
Interface
Electric measurements by a-c methods. 72
Germanium-electrolyte. 570
Gold electrolyte. Adsorption of hydrocarbons. 1075
Heterogeneous. Bond. 712
Solid-melt. 338
See also Surface
Interferometry. Zinc-zinc sulfate-zinc system. 820
Iodides. *See* Cuprous iodide
Iodine. *See* Germanium-iodine system
Iodoform. Electrolytic preparation. 294
Ion association. Alkaline earth chlorides. 311
Ion exchange
Membranes
Fuel cell. Properties. 1173
Transport numbers. 577
Film on passive iron and steel. 644
Single crystal zinc and silver. 1261
Ions
Metal. Simultaneous discharge. 1030
See also Electrolysis
Iridium. Electrochemical corrosion. 947
Iridium crucibles. Repair. 467
Iron
Adsorption by lithium fluoride. 1088
Corrosion inhibition. Methyl pyridines. 507
Oxidation. Effect on ferrous ion and pH. 670
Passivity
Influence of film thickness. 640
Ion-exchange properties of film. 644
Surface studies. 318
Single crystal surfaces. 654
See also Ferro-ferricyanide system. Ferrous ion. Steel
Iron carbide. *See* Cementite
Iron-chromium alloys
Evaporation. 997
Oxide structures. 1195
Passivity. 633
Transpassive region. 628
Iron-nickel alloys. Magnetic properties. 98
Iron oxides
Cathode reactants in thermal cells. 469
Thin layers. Thermodynamic properties. 640

Junction
Delineation by chemical staining. 1018
Diffused. In gallium arsenide lasers. 1153
See also Epitaxial junctions
"Junction lag". In silicon films. 394

Kinetics
Autodoping of germanium. 1065
Constants for lead chloride scale formation. 504
Electrode
Copper deposition. 895
Tungsten, antimony and phosphorus chlorides. 306
Electrodeposition of metal monolayers. 1035
Electro-oxidation of organic compounds. 1002
Oxidation of zirconium and niobium beryllides. 1103
Semiconductor dissolution. 513
Knudsen cell. Interpretation of vapor-pressure measurements. 563

Lamp. *See* Fluorescent lamp. Filament
Lasers
Gallium arsenide. Diffused junctions. 1153
Ruby. Determination of chromium. 1160
Lead
Chlorination. Paralinear kinetics. 504
Growth twins. 463, d. 1291
Oxidation in sulfuric acid. 1
See also Manganese-lead-bismuth system
Lead chloride. Scale formation. 504
Lead dioxide
Action of superimposed a-c. 1
Recovery from polarization. 945
Lead selenide. Photoconductive layers. 174
Lead telluride. Crystal growth. 584
Leak detection. ed. 132C
Leclanche battery. Impedance. 1091
Leclanche cell. Impedance. 1091
Lithium. Reaction with water vapor. 141
Lithium fluoride. Etching of crystals. 1088
Lithium hydroxide. Film formation. 141
Lithium hydride. Electrode. d. 590
Lithium sulfate-sodium sulfate-potassium sulfate system. Electrochemistry. 314
Luminescence
Field-induced. Powdered phosphors. 750
Host. 23
Magnesium oxide-germanium dioxide-silicon dioxide-titanium dioxide system. 726
Zinc sulfide phosphors. 366
See also Cathodoluminescence. Electroluminescence. Phosphor. Photoluminescence. Thermoluminescence

Magnesium
Difference effect in acid solution. 1117
Disintegration. 357
Passive metal. 1113
Magnesium germanide
Solid solution in magnesium silicide. 127
Thermal conductivity. 121
Magnesium oxide. *See* Barium oxide-magnesium oxide-phosphorus pentoxide system
Magnesium oxide-germanium dioxide-silicon dioxide-titanium dioxide system. 726
Magnesium silicide
Solid solution in magnesium germanide. 127
Thermal conductivity. 121
Magnesium silicide-magnesium germanide system. Thermoelectric properties. 127
Magnetism. Iron-nickel electroplate. 98
Manganese. Passivity in acid solutions. 703
Manganese-lead-bismuth system. Thermodynamic properties. 792
Manganic sulfate. Electrolytic regeneration. 202
Masers. Ruby. Determination of chromium. 1160
Mercuric halides. Vibrational frequencies. 1023
Mercury. Corrosion of carbon steel. 964
Metal
Ions. Simultaneous discharge. 1030
Monolayers. Electrodeposition. 1035
Methanol. Oxidation on platinum. 449
Methyl pyridines. Corrosion inhibitors. 507
Microhardness. Wurtzite compounds. 773
Molybdates. *See* Europium molybdates. Terbium molybdates
Molybdenum
Oxidation. 952
See also Nickel-molybdenum alloys
Molybdenum-nickel alloys. Corrosion and passivity. 650
Molybdenum trioxide. Vapor pressure. 242
Neutron activator. For chromium determination. 1160
Nickel
Anodic oxidation. Crystal structure. 484
Anodic passivation in sulfuric acid. 605
Anodic polarization. 1007
Electrodeposits. Corrosion rates. 1087
Electroless deposition. Thiourea. 890
Hydrogen evolution. 86
Oxidation
High-pressure. 185
Rates. 1014

Reaction with fluorine. 346
See also Copper-nickel-zinc alloys. Iron-nickel alloys. Molybdenum-nickel alloys
Nickel-aluminum oxide alloys. Electrodeposition. 557
Nickel-hydrogen system. Electrochemistry. 444
Nickel-molybdenum alloys. Electrodeposition. 362
Niobium. Electrode. Photogalvanic effect. 1163
Niobium beryllide. Oxidation kinetics. 1103
Niobium pentoxide. *See* Zinc oxide-niobium pentoxide
Nitrate ion. Reduction. 814
Nitrates. *See* Alkali nitrates. Potassium nitrate. Sodium nitrate. Thallium nitrate
Nitrides. *See* Titanium nitride
Nitrites. *See* Alkali nitrites
Nitrobenzene derivatives. Polarographic reduction. 995

Optical anisotropy. Aluminum oxide films. 262
Optics. Passive films on iron crystals. 654
Organic compounds
Electrochemical characteristics. 353
Electro-oxidation. Kinetics. 1002
Sulfur. Electrochemical characteristics. 353
See also Acetonitrile. Alcohols. Aryl sulfonium salts. Benzene. Benzyne. Dicyandiamide. Dimethylformamide. Ethenes. Formamide. Hydrocarbons. Iodoform. Methanol. Methyl pyridines. Nitrobenzene derivatives. Perylene. Phthalocyanines. Pyridine. Thiourea. Tolualdelydes
Oscillopolarogram. Single-sweep. 926
Overpotential
Copper deposition. 895
Activation. Analog solutions. 222
Oxidation
Boron carbide. 921
Graphite. 476
High-pressure. Nickel in oxygen. 185
Hydrocarbons. By manganic sulfate. 202
Iron. Effect of ferrous ion and pH. 670
Iron-chromium alloys. Structures. 1195
Lead. 1
Molybdenum. 952
Nickel
High-pressure. 185
Rates. 1014
Niobium beryllide. Kinetics. 1103
Silicon. 527, *d.* 1292
Tantalum
High-temperature. 490
Stress generation. 551
Tin. Effect of alloying elements. 4
Uranium-copper alloy. 1146
Zinc. Effect of electric field. 461
Zircaloy-2. 1110
Zirconium and its alloys. 960
Zirconium beryllide. Kinetics. 1103
See also Anodic oxidation. Electrochemical oxidation. Electro-oxidation. Redox systems. Reduction
Oxide films
Aluminum
Distribution of a-c resistance. 1205
Initiation of pores. 614
Germanium. Formation. 914
Iron. Influence of thickness. 640
Lead. 1
Metals
Formation. 1240
Valence changes. 680
Platinum. Formation and dissolution. 826
Silicon. Optical properties. 983
Stainless steel. Crystal structure. 1177
Tantalum. Heat treatment. 1264, 1271
Tin. 4
Titanium. 65
See also Passivation
Oxide layers. Tungsten. Structure. 502
Oxides
Refractory. Reactions with graphite. 783
See also Aluminum oxide. Beryllium oxide. Cadmium oxide. Germanium oxide. Hafnium oxide. Iron oxides. Lead dioxide. Magnesium oxide. Molybdenum trioxide. Niobium pentoxide. Platinum oxide. Silicon dioxide. Silicon oxide. Stannic oxide. Tantalum pentoxide. Titanium dioxide. Titanium oxides. Tungsten oxides. Zinc oxide. Zirconium dioxide
Oxygen
Diffusion in hafnium. 943
Effect on cuprous iodide conductivity. 119
Evolution on platinum electrode. 332
Normal potential on platinum. 1019
Transport at copper cathode. *d.* 591

Passivation
Aluminum in acid solution. 614
Chromium. In transpassive region. 628
Growth of layers on metal surfaces. 688
Iridium electrodes. 947
Iron-chromium alloys. 628
Nickel in sulfuric acid. 605
Zinc in potassium hydroxide. 95
See also Oxide film
Passivity
Copper-nickel-zinc alloys. 1215
Electrodes. Thermodynamic theory. 596
Iron. Surface studies. 318
Iron-chromium alloys. 633
Magnesium. 1110
Manganese in acid solution. 703
Molybdenum-nickel alloys. 650
Symposium, Second International, 1962. 596
See also Coating, Passive. Corrosion, Passive. Electrode, Passive. Film, Passive. Iron, Passivity. Steel, Passive. Transpassive region
Peritectic compound. In cadmium telluride-indium telluride system. 1132
Perovskites. Epitaxial vapor deposition. 969
Perylene-metal halide complexes. 769
Pesticide control. *ed.* 229C
pH. Effect on passive iron. 670
pH-stat. Electrochemical. 1183
Phase diagram. For cadmium telluride-indium telluride system. 1127
Phase equilibrium
Titanium-oxygen system. 92
Zinc phosphate-cadmium phosphate system. 1218
Phosphates
Anion deposition. 853
See also Barium oxide-magnesium oxide-phosphorus pentoxide system. Barium oxide-zinc oxide-phosphorus pentoxide system. Halophosphates. Thorium phosphate
Phosphides. *See* Gallium phosphide
Phosphor
Cadmium chlorophosphate. 113
Calcium fluoride. 340
Fluorescent lamp. Ultraviolet radiation. 36
Halophosphate. 36
Powdered. Luminescence. 750
Self-activated. 23
Thorium phosphate. 280
Zinc-cadmium sulfide
Coactivator emission. 28
Emission spectra. 754
Zinc-magnesium sulfide. 979
Zinc oxide. Doping. 381
Zinc sulfide
Coactivator emission. 28
Electroluminescence. 370, 1045
Influence of copper. 1228
Ultraviolet excitation. 366
Phosphorus
Dissociation pressure from gallium phosphide. 117
Phosphorus chlorides. Electrode kinetics. 306
Photoconductive detector. Lead selenide. 174
Photoconductivity
Cadmium sulfide crystals. 456
Phthalocyanine. 779
Thin organic films. 543
Zinc sulfide phosphors. 366
Photogalvanic effect
Anodized zirconium and niobium electrodes. 1163
See also Photovoltaic effect
Photoluminescence. Silicon carbide. 517
Photovoltaic effect
Titanium oxide films. 846
See also Photogalvanic effect
Phthalocyanine. Photoconductivity. 779
Pi-complex. Cobalt, chromium, and titanium. Polarography. 1085
Planar complex. Electrodeposition. 716
Platinum
Electrode
Hydrogen ionization-oxygen evolution. 332
Hydrogen oxidation. 145, 152
In sulfuric acid. 1142
Normal oxygen potential. 1019
Oxidation of methanol. Kinetics. 449
Platinum oxides. Formation and dissolution of film. 827
Point defect. Influence on semiconductor dissolution. 513
Polarization
Anodic. Nickel. 1007
Cathodic. Tin electrodeposition. 190
Concentration in fuel cells. 209
Lead dioxide. Recovery from. 945
Polarographic reduction
Nitrobenzene derivatives. 995
Phenyl-substituted ethenes. 225, 231
Polarography
In acetonitrile. 420
In dimethylformamide. 420, 1085
In formamide. 1085
In pyridine. 160
Of pi-complexes of cobalt, chromium, and titanium. 1085
Polishing
Chemical. Gallium arsenide. 585
See also Electropolishing
Polymerization. Glow discharge process. 15
Pore. Formation in aluminum oxide. 614
Potassium nitrate. *See* Sodium nitrate-potassium nitrate
Potential
Distribution at germanium-electrolyte interface. 570
Normal oxygen. On platinum. 1019
Of passive electrodes. 597
Thermoelectric. Of perylene-metal halide complexes. 769
See also Current. Electromotive force. Overpotential. Rest potential. Streaming potential
Pressure
Effect on conductivity of electrolytes. 1282
Of water, negative. As indicator. 1136
See also Dissociation pressure. Vapor pressure
Probe. Four-point, for resistivity measurements. 538
Propane. Fuel cell. 1086
Pulse excitation. Electroluminescent films. 41
Pyridine
Electrochemistry. As solvent. 160
See also Methyl pyridines
Pyrochlore fluoantimonates. X-ray study. 1048
Pyrolysis
Deposition of silicon dioxide films. 361
Monosilane. Reaction kinetics. 1235
Radiation. *See* Infrared radiation. Ultraviolet radiation. X-ray
Radioactive tracer
Study of zone refining of gallium trichloride. 60
Study of thiourea in electroless deposition. 890
See also Hydrogen, Isotopes. Tritium
Redox system
Carbides and nitrides as electrodes. 847
Ferro-ferricyanide. 237
Reduction
Dicyandiamide. 918
Oxygen on passive zirconium. 167
See also Electrochemical reduction. Electroreduction. Polarographic reduction. Oxidation
Regeneration
Electrolytic. Manganic sulfate. 202
Thermal. Liquid-metal cell. 1097
Resistance
A-c distribution in aluminum oxide. 1205
Diaphragms. Effectiveness. 1257
See also Impedance
Resistivity
Probe for measurements. 538
See also Electrical resistivity
Rest potential. Gold-oxygen-acid system. 245
Retirement plan. *ed.* 83C
Ruby. Maser and laser crystals. 1160

Scale. Volatile. Formation. 504
Selenides. *See* Lead selenide
Selenium. *See* Tungsten-tantalum-selenium system
Semiconductor
Cadmium oxide. Properties. 548
Dissolution kinetics. Point defects. 513
Epitaxial layers. Close spacing. 1165
Gallium and indium. Solubilities. 385
Mixed valency anion. 119
New ternary compounds. 766
Peritectic compounds from cadmium telluride system. 1132
Resistivity. Probe for measuring. 538
Stannic oxide. 1081
See also particular semiconducting substances, e.g. Germanium. Silicon
Silane. Pyrolysis. Kinetics. 1235
Silicides. *See* Magnesium silicide
Silicon
Diodes. Gettering of impurities. 533

Electropolishing. 412
Epitaxial films. 1252
Epitaxial growth
From monosilane. 1235
Junctions. 394
Gold plating. 239
Molten. Source of silicon carbide. 84
Oxidation in oxygen and steam. 527, *d.* 1292
Oxide films. Optical properties. 983
Surface energy. 524, *d.* 1293
Thermal etching of surfaces. 82
Twin boundaries. Properties. 52
Vapor grown. Stacking faults. 388
See also Germanium-silicon alloys
Silicon carbide
Formation in electric arc. 298
Growth from molten silicon. 84
Photoluminescence. 517
Silicon dioxide
Deposition by hydrolysis of silicon tetrabromide. 361
Films. Optical properties and growth. 983
See also Magnesium oxide-germanium dioxide. silicon dioxide-tantalum dioxide system
Silicon oxide. Films
Deposition at low temperatures. 465
Evaporated. 271
Silicon tetrabromide. Hydrolysis. 361
Silver
Electrodeposited. Effect of additives. 103
Single-crystal. Ion exchange with zinc. 1261
Sintering. Tungsten with group VIII elements. 805
Sodium. Liquid. Oxidation of zirconium. 960
Sodium borohydride. Anodic fuel. *d.* 591
Sodium nitrate. Transference numbers. 810
Sodium nitrate-potassium nitrate. Reduction of nitrate. 814
Solid solution. Hafnium carbide and uranium monocarbide. 560
Spectra. *See* Emission spectra
Spectroscopy. Study of anodic oxidation. 849
Spinel
Cobalt sulfide-indium sesquisulfide. 593
Zinc oxide-niobium pentoxide. 205
Stacking fault. Vapor grown silicon. 388
Stannic oxide. Semiconduction. 1081
Stannous sulfate. Solution for electrodeposition of tin. 190
Steel
Carbon. Corrosion by liquid mercury. 964
Corrosion. Pole of cementite. 1121
Embrittlement by hydrogen isotopes. 867, 877
High strength. Embrittlement. 867
Passive. Properties of film. 644
Stainless. Structure of oxide films. 1177
Streaming potential. Measurement at glass-liquid interfaces. 72
Stress
In anodic films. 345, *d.* 1289
In tantalum during oxidation. 551
Sulfates. *See* Lithium sulfate. Manganic sulfate. Potassium sulfate. Sodium sulfate. Stannous sulfate
Sulfides. *See* Cadmium sulfide. Bismuth sulfide. Cobalt sulfide. Indium sesquisulfide. Zinc sulfide
Sulfur compounds
Electrochemical characteristics. 353
See also Sulfides. Sulfates. Thiourea
Surface
Masking in gallium arsenide. 341
Metal. Growth of passivating layers. 688
Passive iron. 318
Silicon. Thermal etching. 82
Titanium. Electrochemical oxidation. 65
See also Film
Surface energy
Germanium and silicon. 524, *d.* 1293
Surface tension. Salt solutions. Electrostatic fields *d.* 590

Tantalum
Anodes. Prepared in situ. 12
Anodic oxide films. Heat treatment. 1264, 1271
Anodized films. Residual water. 938
Gettering properties. 1072
Oxidation behavior. 491
Stress generation during oxidation. 551
See also Tungsten-tantalum-selenium system
Tantalum carbide. Electrode in redox system. 847
Tantalum pentoxide
Anodic films
Flaws. 250, *d.* 1286
Heat treatment. 1264, 1271
Ionic conduction. 589
Reaction with carbon to form anodes. 12
Tellurides. *See* Cadmium telluride. Germanium telluride. Lead telluride. Zinc telluride
Terbium molybdates. Emission intensities. 46
Terbium tungstates. Emission intensities. 46
Thallium nitrate. Transport number. 91
Thermal cell. Magnesium/lithium chloride-potassium chloride/iron oxide, nickel. 469
Thermal conductivity. Of magnesium silicide and magnesium germanide. 121
Thermal etching. *See* Etching, thermal
Thermal expansion. Of titanium carbide, zirconium carbide, and hafnium carbide. 587
Thermodynamics
Hydrocarbon fuel cells. 1025
Potential theory of passive electrodes. 597
Properties of manganese-lead-bismuth system. 792
Thin oxide films. 640
See also Entropy. Phase equilibrium
Thermoelectricity
Magnesium silicide-magnesium germanide system. 127
Perylene-metal halide complexes. 769
Tungsten-tantalum-selenium system. 289
Thermoluminescence. Calcium fluoride-manganese phosphor. 340
Thioures. Effect on electroless nickel deposition. 890
Thorium
Carbide-iodide. Physical properties. 429
Filament temperatures. 135
Thorium phosphate. Phosphors. 280
Throwing power. Current in anodic and cathodic protection. 698
Tin
Alloy. Layers isolated from tinplate. 176
Electrochemistry. Effect of additives. 190
Oxidation. Effect of alloying elements. 4
See also Gold stannides. Stannic oxide. Stannous sulfate
Tinplate. Electrolytic. Alloy layers. 176
Titanium
Surfaces. Electrochemical oxidation. 65
See also Pi-complexes of titanium
Titanium carbide
Electrode in redox system. 847
Thermal expansion. 587
Titanium dioxide. *See* Magnesium oxide-germanium dioxide-silicon dioxide-titanium dioxide system
Titanium nitride. Electrode in redox system. 847
Titanium oxides. Photovoltaic effect. 846
Titanium-oxygen system. Phase equilibria. 92
Tolualdehydes. Preparation. 202
Transfer coefficient. Ferro-ferricyanide system. 237
Transference number
In sodium nitrate. 810
Of alkaline earth chlorides. 311
Transpassive region. Behavior of chromium and iron-chromium alloys. 628
Transport
Chemical systems for growing layers of semiconductors. 1165
Gallium arsenide. 1059
Ions through membranes. 577
Transport numbers
Alkali nitrates and nitrites. 91
Bicarbonate, carbonate, and chloride ions. 577
Thallium nitrate. 91
Tritium. For water detection. 938
Tungstates
Anion deposition. 853
See also Europium tungstates. Terbium tungstates
Tungsten
Oxide layers. Structure. 502
Sintering with group VIII elements. 805
Tungsten carbide. Electrode in redox system. 847
Tungsten hexachloride. Electrode kinetics. 306
Tungsten oxides. Structure. 502
Tungsten-tantalum-selenium system. Thermoelectric properties and x-ray study. 289
Tunnel diode
Alloyed gold contacts to silicon and germanium. 239
Gallium arsenide. Degradation. 178
Twin boundaries, Silicon crystals. 52

Ultraviolet radiation. Fluorescent lamp phosphors. 36
Uranium-copper alloy. Oxidation. 1146
Uranium monocarbide. Solubility with hafnium carbide. 560
Uranyl (VI). Electroreduction. 1277

Vacuum deposition. Silicon oxide films. 271
Vacuum evaporation. Cadmium telluride. 407, *d.* 1291
Valence. Changes on surface oxide films. 680
Vapor growth. Germanium-silicon films. 1068
Vapor pressure
Solids in Knudsen cells. 563
Molybdenum trioxide. 242
Vibrational frequency. Mercuric halides. 1023
Viscosity. Alkali carbonates. 452

Water vapor. Reaction with lithium. 141
Wetting. Germanium by indium. 904
Woodward retirement plan. *ed.* 83C

X-ray
Diffraction study of cadmium sulfide. 1083
Study of pyrochlore fluoantimonates. 1048
Study of tungsten-tantalum-selenium system. 289
Xylenes. Oxidation by manganic sulfate. 202

Zero charge point. Metal electrodes. 466
Ziegler electrolyte. Germanium electrodes 1054
Zinc
Anodic behavior in potassium hydroxide. 95
Atmosphere. Effect of zinc sulfide. 79
Oxidation. Effect of electric field. 461
Single-crystal. Ion exchange with silver. 1261
See also Copper-nickel-zinc alloys
Zinc antimonide. Dissociation pressure. 88
Zinc-cadmium sulfide phosphors
Coactivator emission. 28
Electroluminescence. 759
Emission spectra. 754
Zinc-magnesium sulfide phosphors. Electroluminescence. 979
Zinc oxide
Phosphors. Doping. 381
See also Barium oxide-zinc oxide-phosphorus pentoxide system
Zinc oxide-niobium pentoxide. Spinel. 205
Zinc phosphate-cadmium phosphate system Manganese-activated luminescence. 1218
Zinc sulfide
Dember effect study. 285
Effect of zinc atmosphere. 79
Electroluminescence. 370
Lines in powder particles. 733
Microhardness. 773
Phosphors
Coactivator emission. 28
Electroluminescence. 370, 1045
Influence of copper. 1228
Luminescence. 366
Photoconductivity. 366
Ultraviolet excitation. 366
Zinc telluride-cadmium sulfide heterojunctions. 401
Zinc-zinc sulfate-zinc system. Interferometric study. 820
Zircaloy-2
Corrosion. 856
Oxidation by steam. 1110
Zirconium
Alloy
Corrosion. Influence of environment. 856
Oxidation. In liquid sodium. 960
Diffusion coefficients for hydrogen in. 799
Electrode. Photogalvanic effect. 1163
Filament temperatures. 135
Passive. Reduction of oxygen. 167
Van Arkel. Corrosion. 856
Zirconium beryllide. Oxidation kinetics. 1103
Zirconium carbide. Thermal expansion. 587
Zirconium dioxide
Defect structure. 181, *d.* 1285
Electrical resistivity. 276
Zone refining
Cadmium telluride. 343
Gallium trichloride. 60